

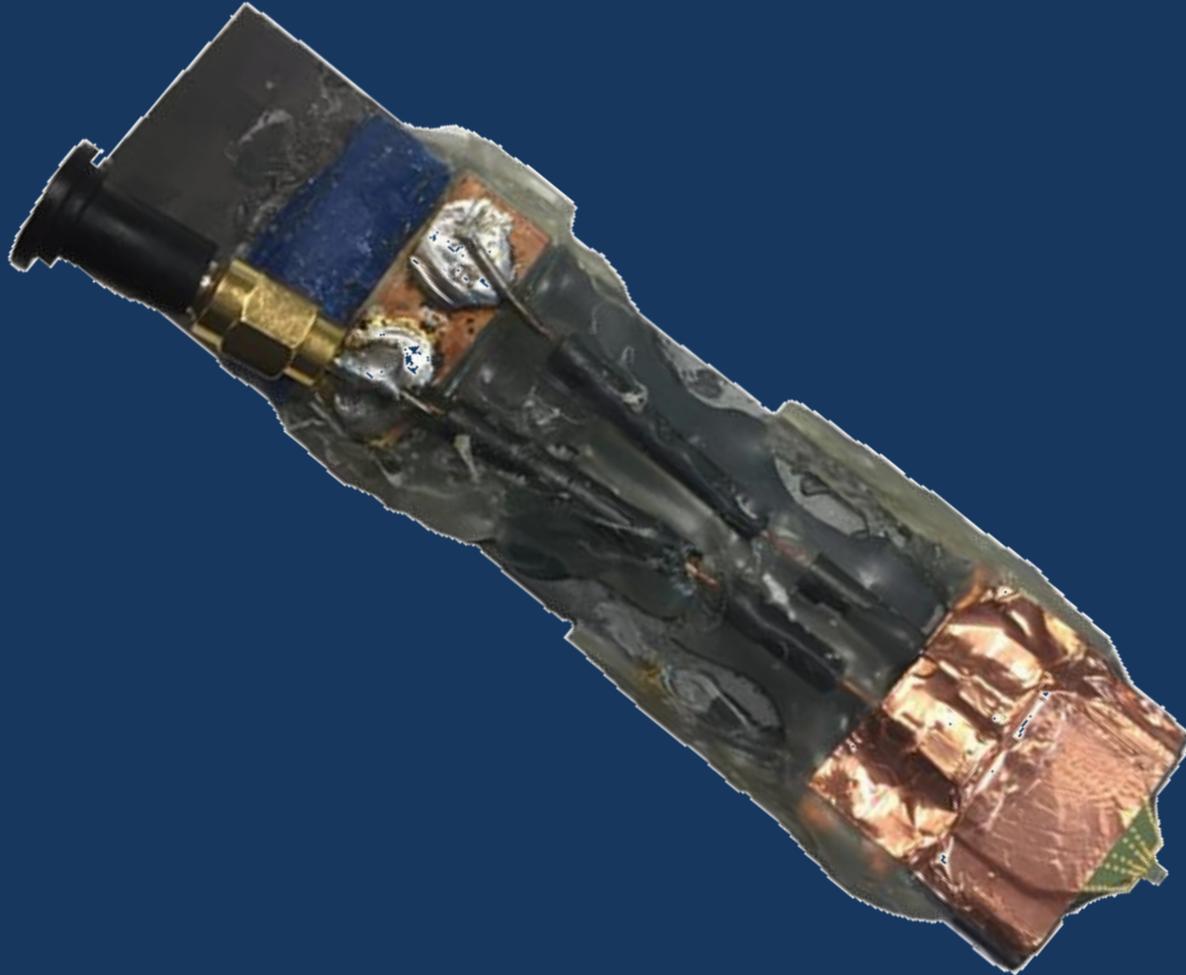
Near-Field Scanning

Searching for Root Causes

- Emission Scanning
 - Sniffer probes are smarter than they look
 - Electromagnetic lens: from near-field to far-field
- Susceptibility Scanning
 - Conducted susceptibility: where does ESD current go?
 - Near-field effects of electrostatic discharge events

Emission Scanning

Sniffer Probe



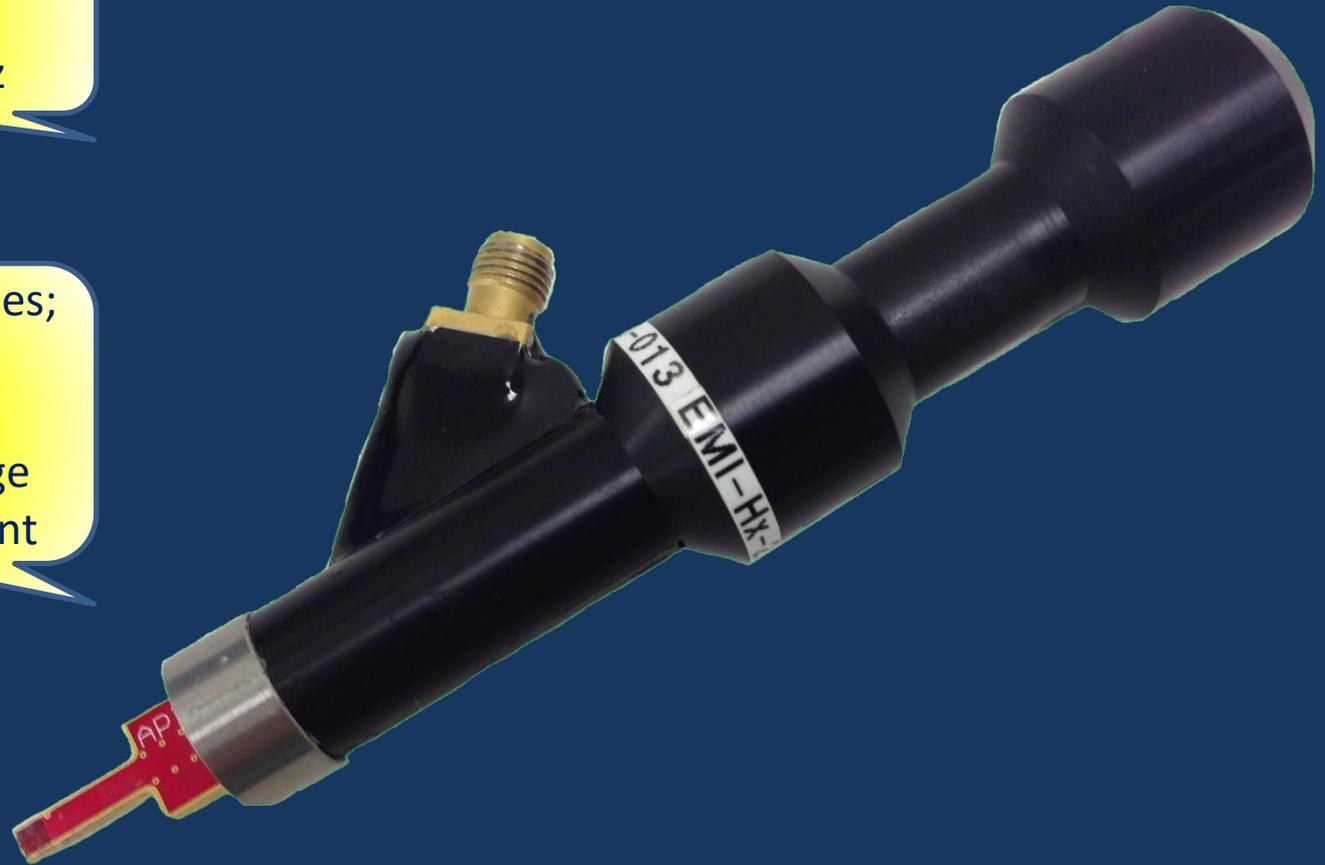
EMI Near-Field Probe

EMI Probes:

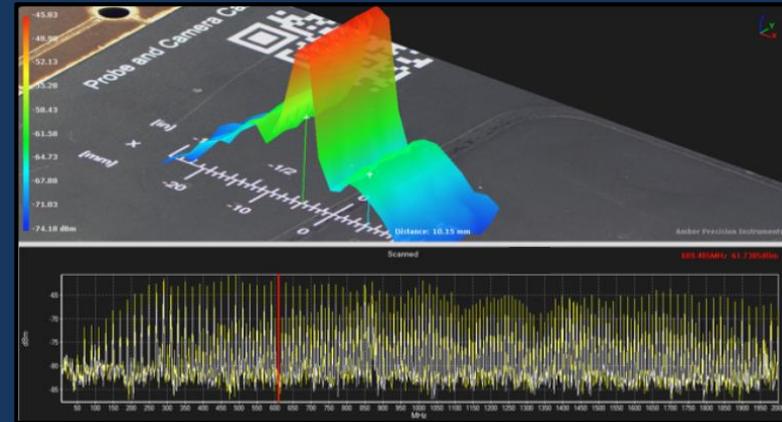
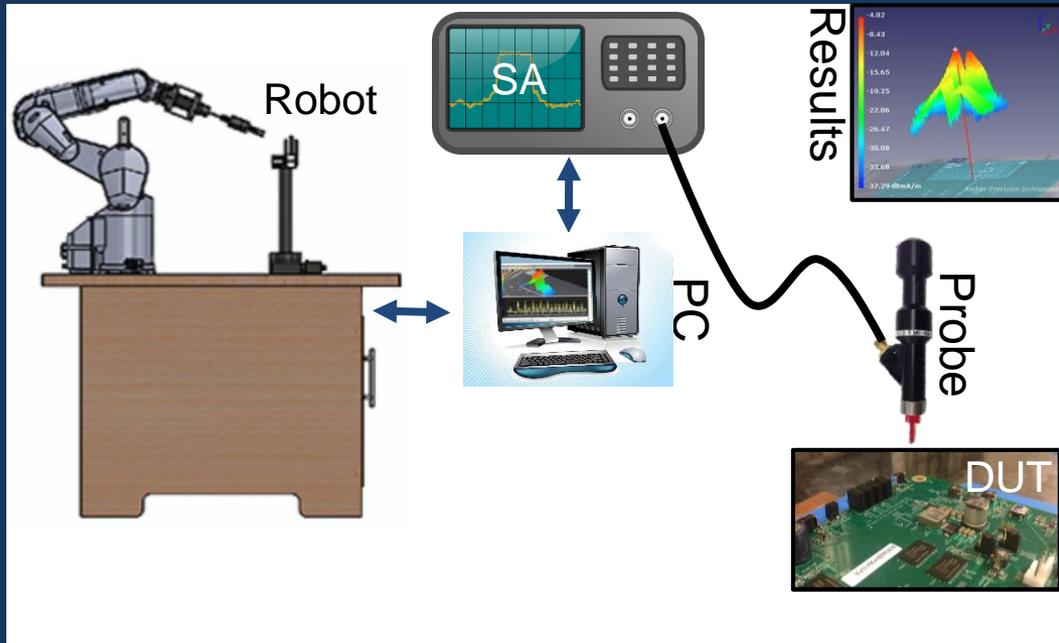
- Up to 40 GHz
- Down to 50 kHz

Optional EMI Probes; Choose:

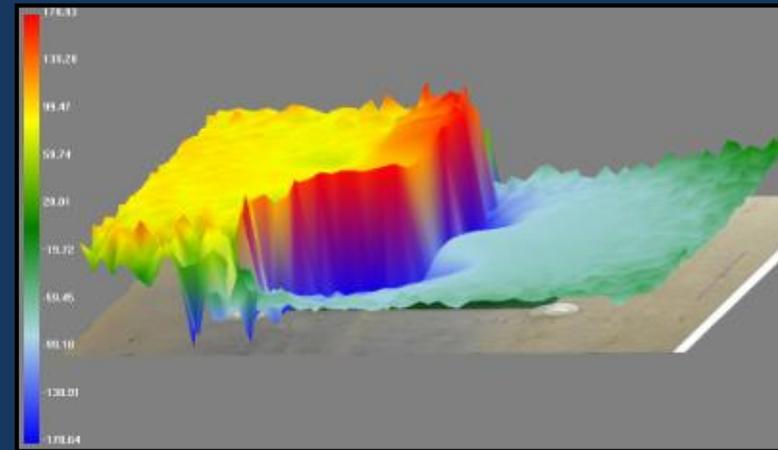
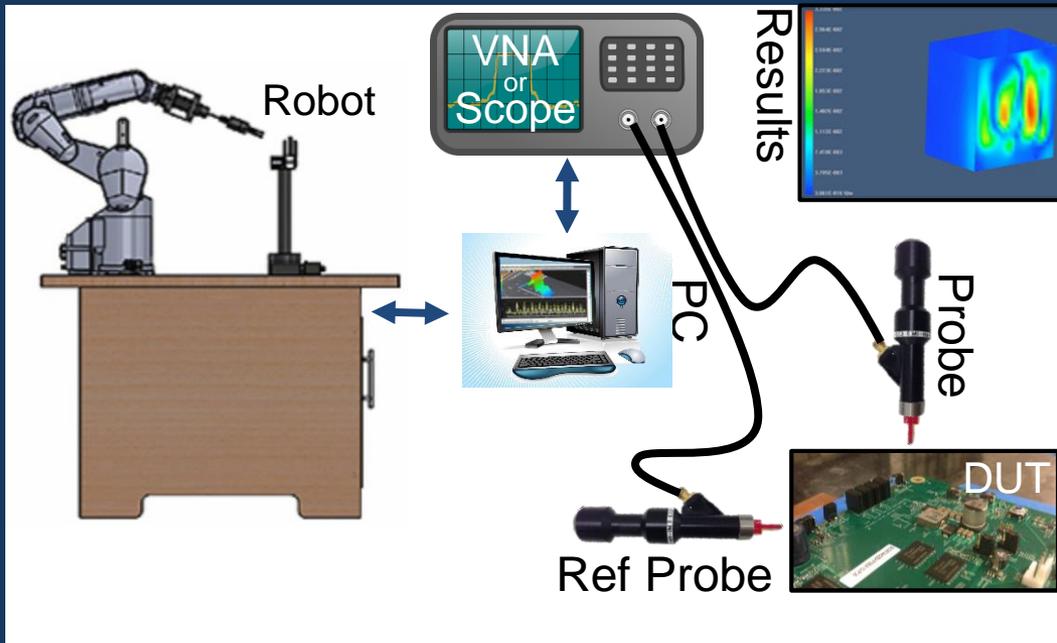
- Size
- Frequency range
- Field Component



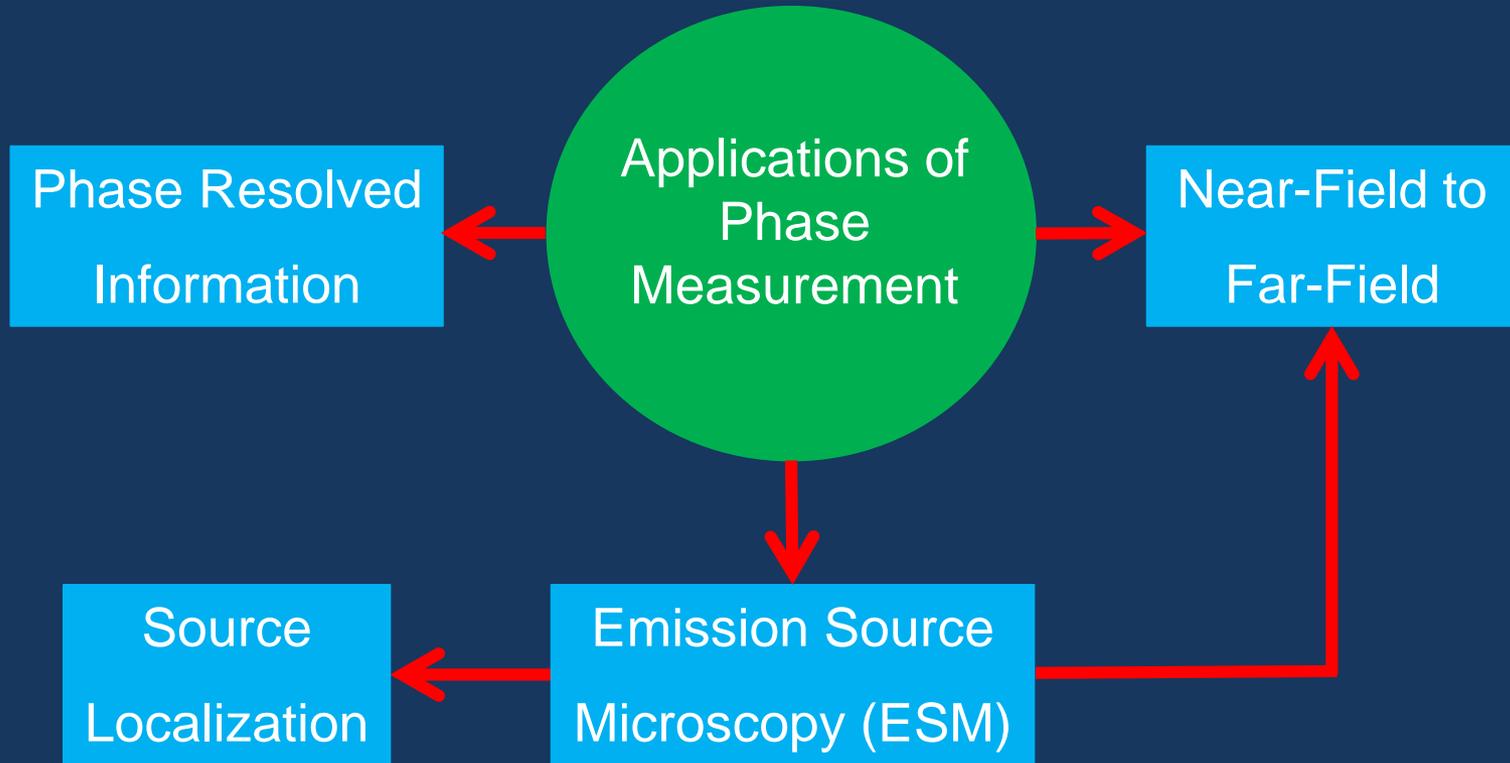
EMI Near-Field Scanning



Phase Measurement Scanning



Applications of Phase Measurement



Applications of ESM:

- High speed data communication
- Data centers, servers, routers, cloud
- 5G mobile network
- Radar systems
- Phased arrays
- Electrically large structures

History of ESM: Synthetic Aperture Radar (SAR)

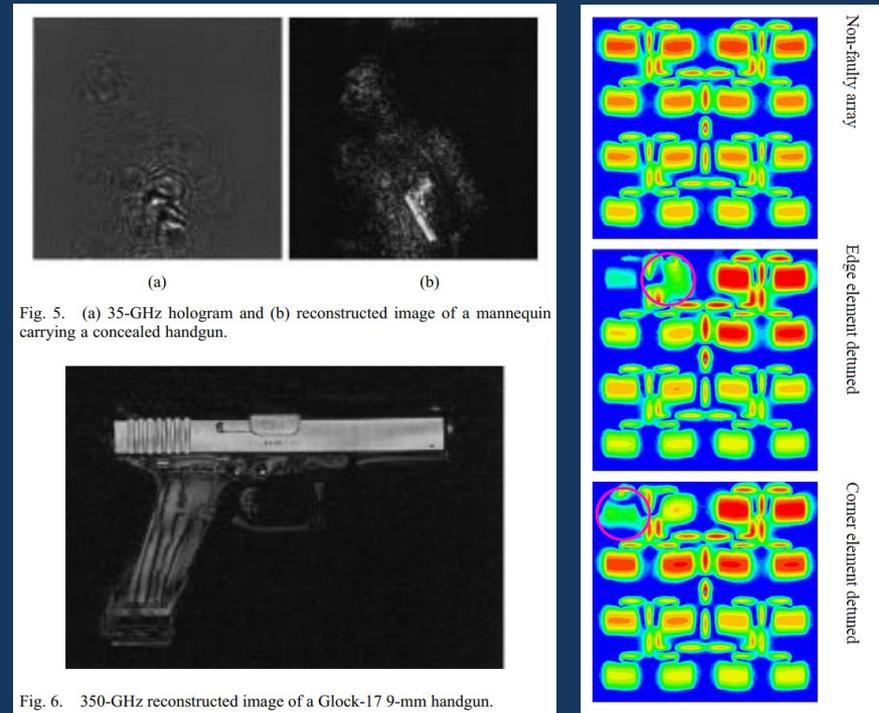
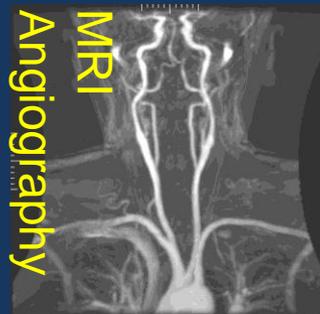
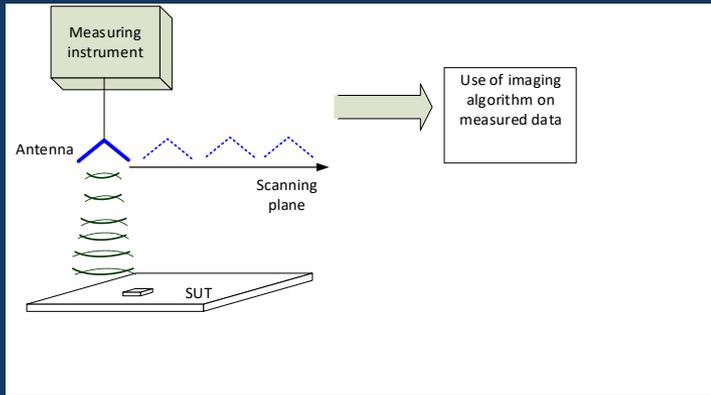
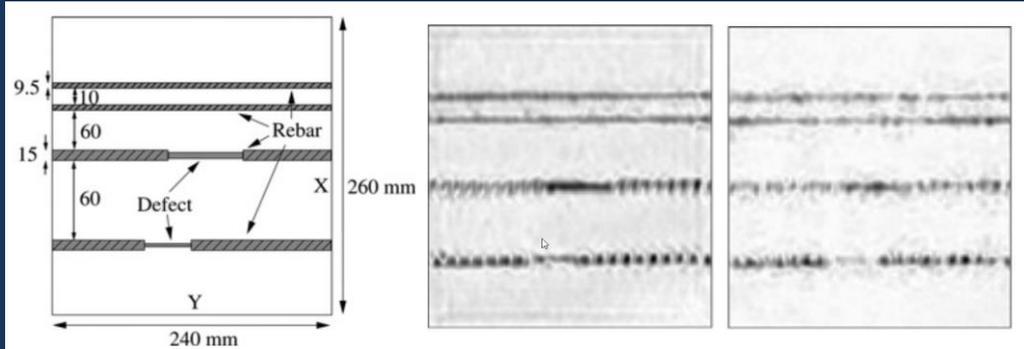


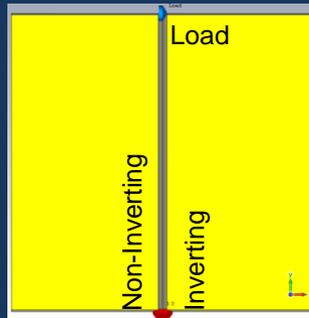
Fig. 5. (a) 35-GHz hologram and (b) reconstructed image of a mannequin carrying a concealed handgun.

Fig. 6. 350-GHz reconstructed image of a Glock-17 9-mm handgun.

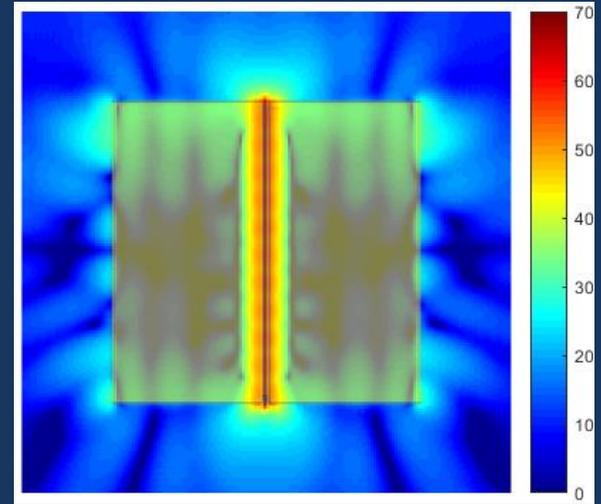
- Applications of SAR:**
- Airborne radar
 - Medical imaging
 - Concealed object detection
 - Non-destructive testing
 - Antenna diagnosis



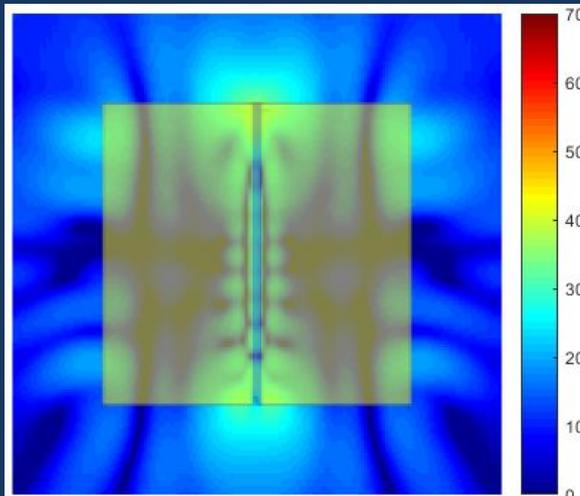
Symmetric Differential Microstrip



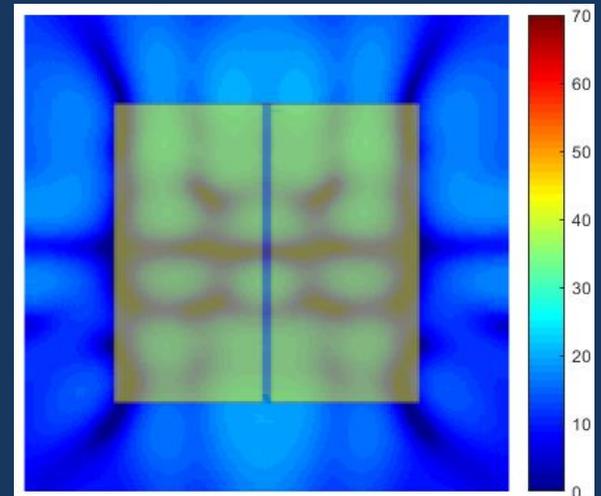
Full-wave simulation
Differential microstrip line
Differentially driven @ 10 GHz



Ex @ Z=1 mm ($\lambda/30$)

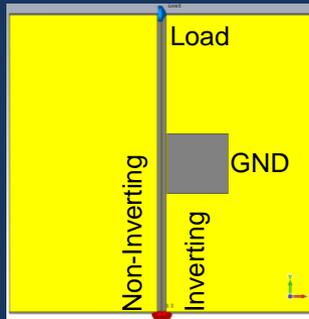


Ex @ Z=7.5 mm ($\lambda/4$)

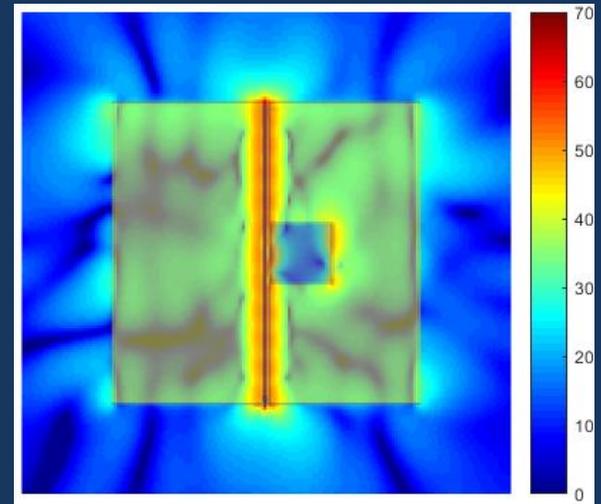


Ex @ Z=30 mm (λ)

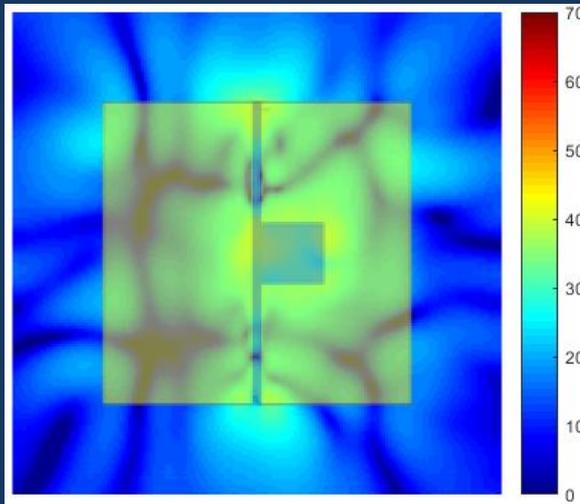
Asymmetric Differential Microstrip



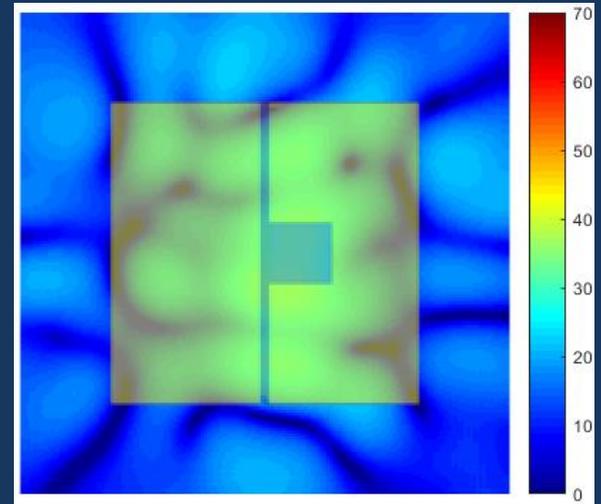
Asymmetric differential microstrip
12 mil gap between GND & line
Differentially driven @ 10 GHz



Ex @ Z=1 mm ($\lambda/30$)

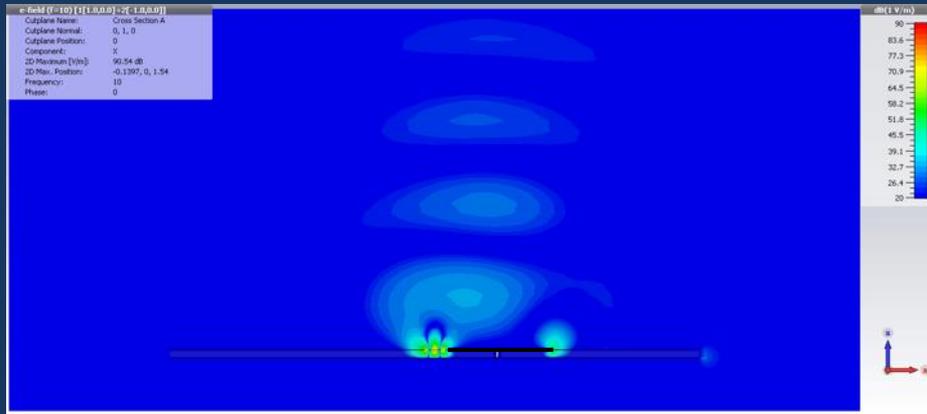


Ex @ Z=7.5 mm ($\lambda/4$)

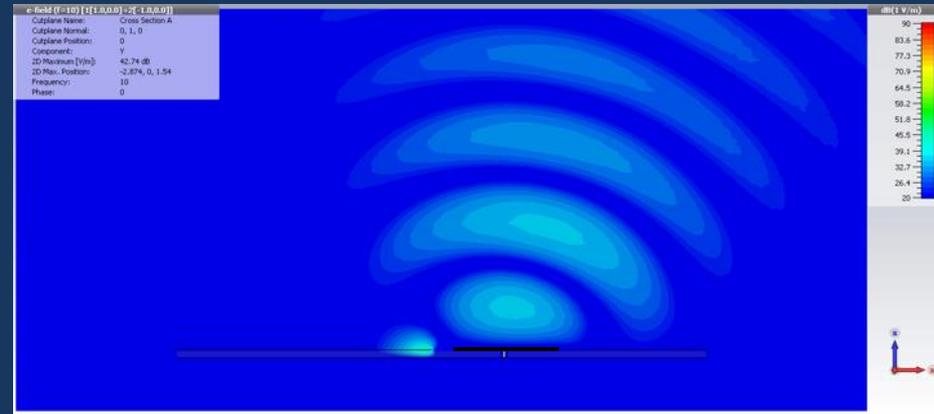


Ex @ Z=30 mm (λ)

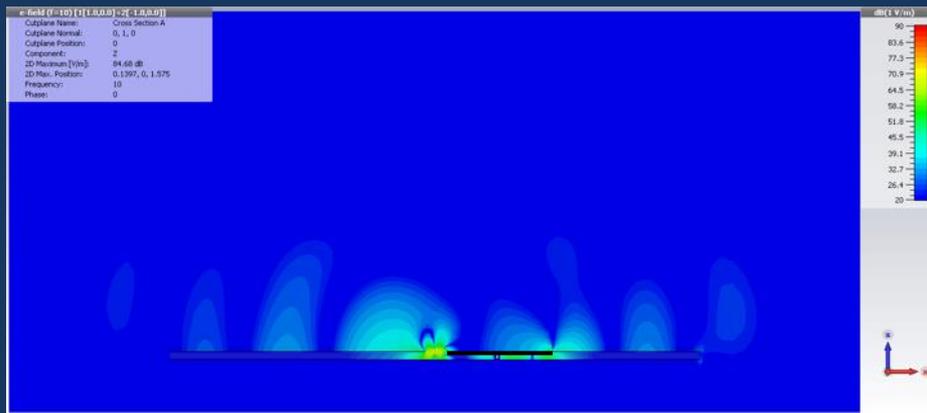
Wave Propagation



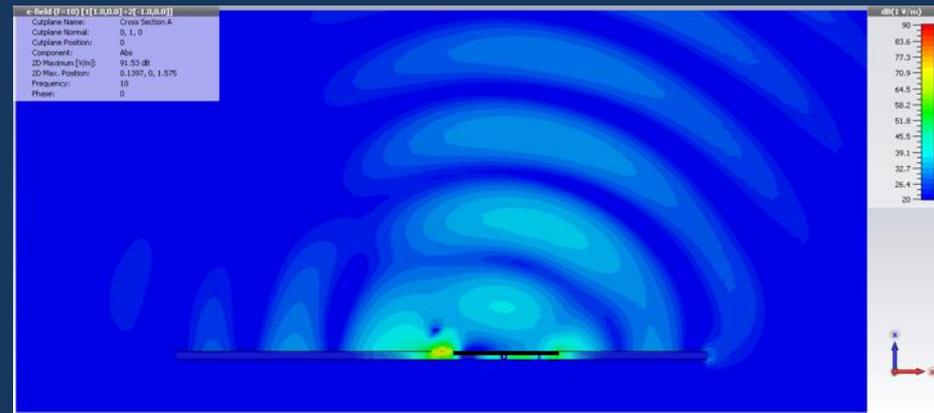
E_x



E_y

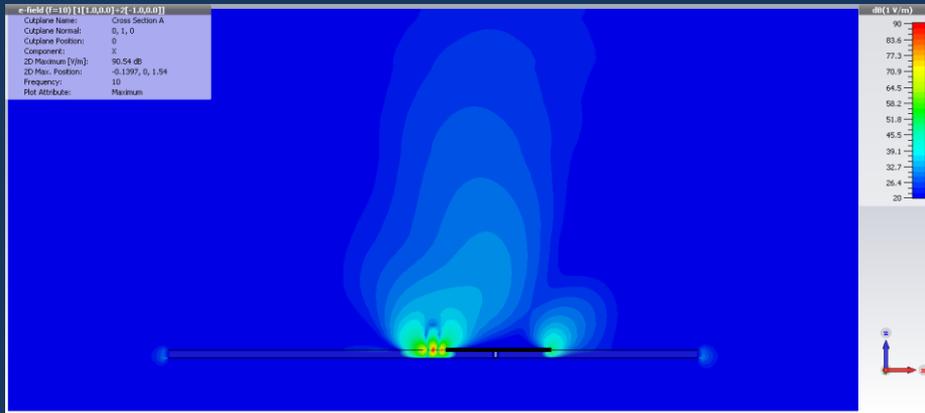


E_z

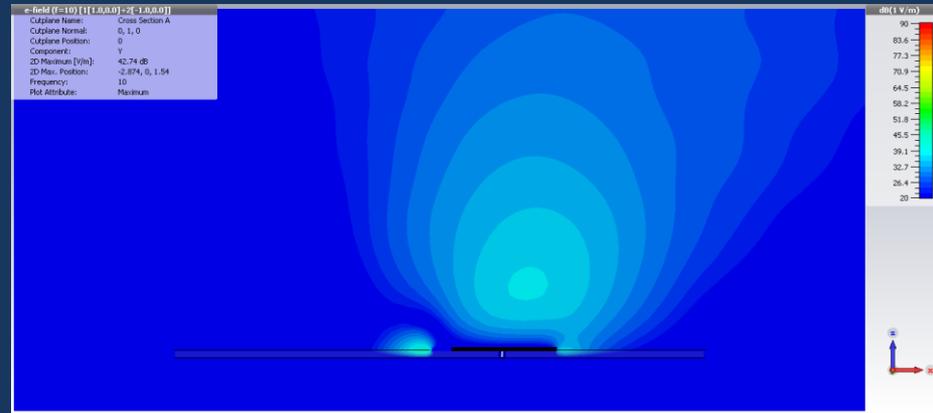


$|E|$

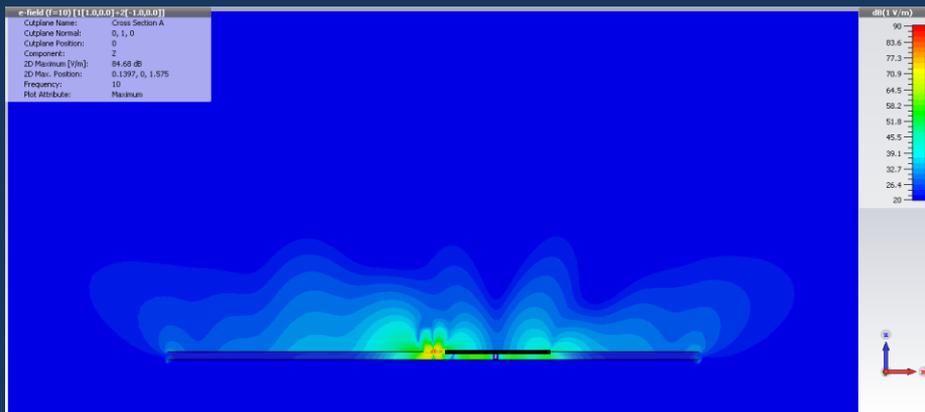
Wave Propagation



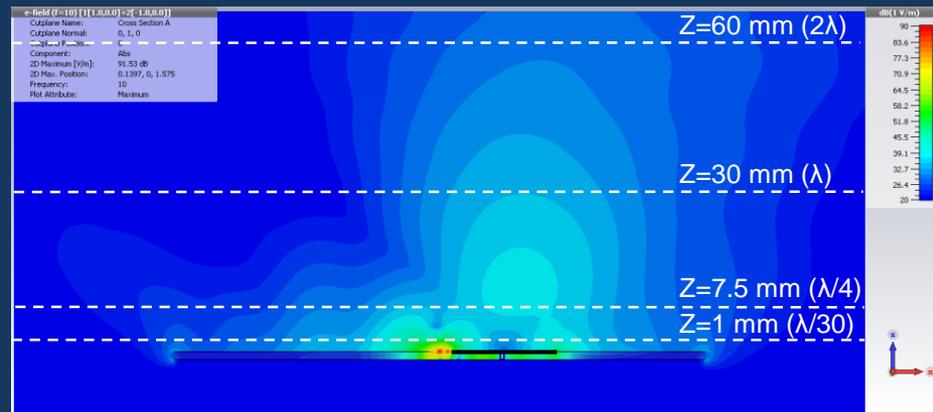
Max Ex



Max Ey

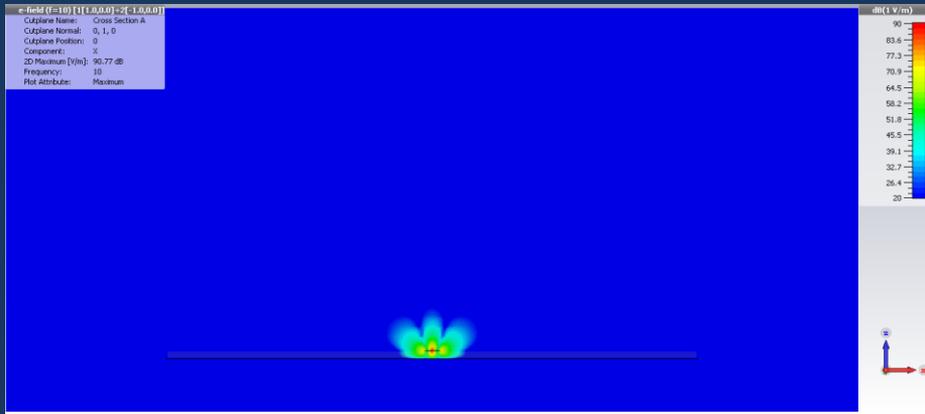


Max Ez

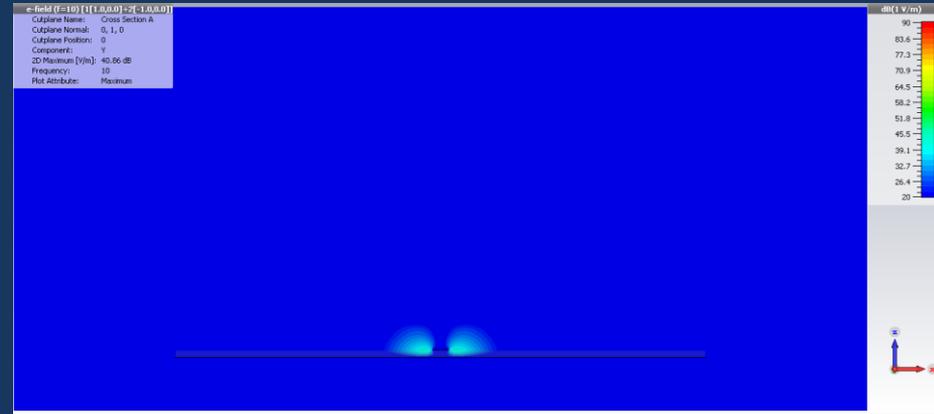


Max |E|

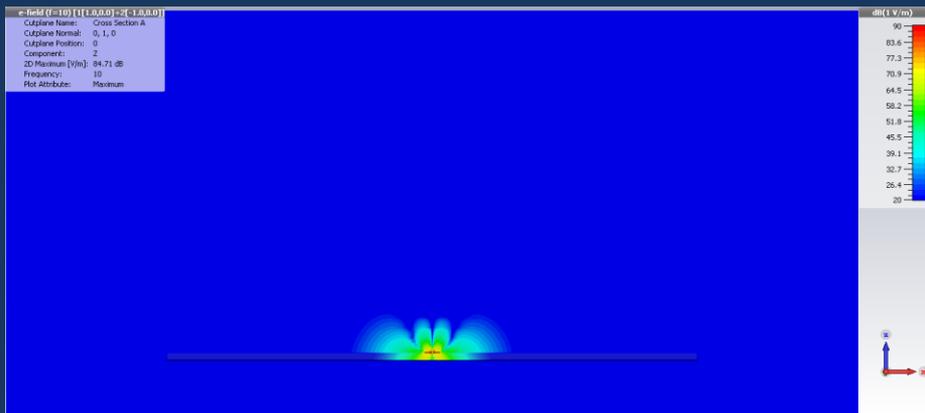
Wave Propagation



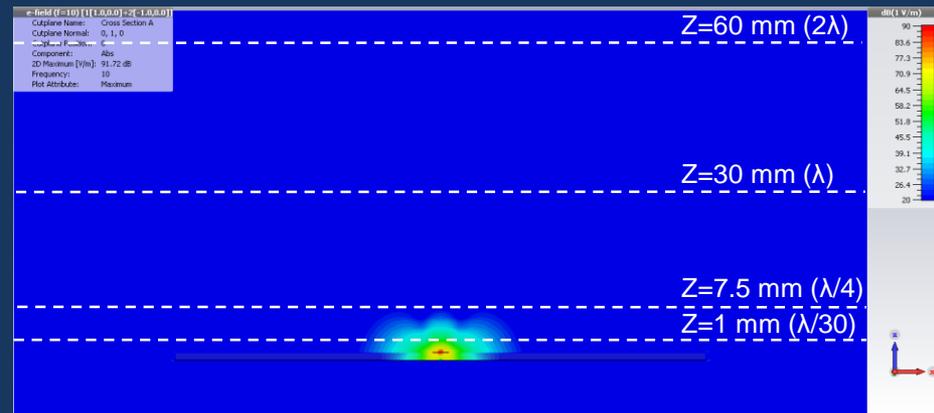
Max Ex



Max Ey



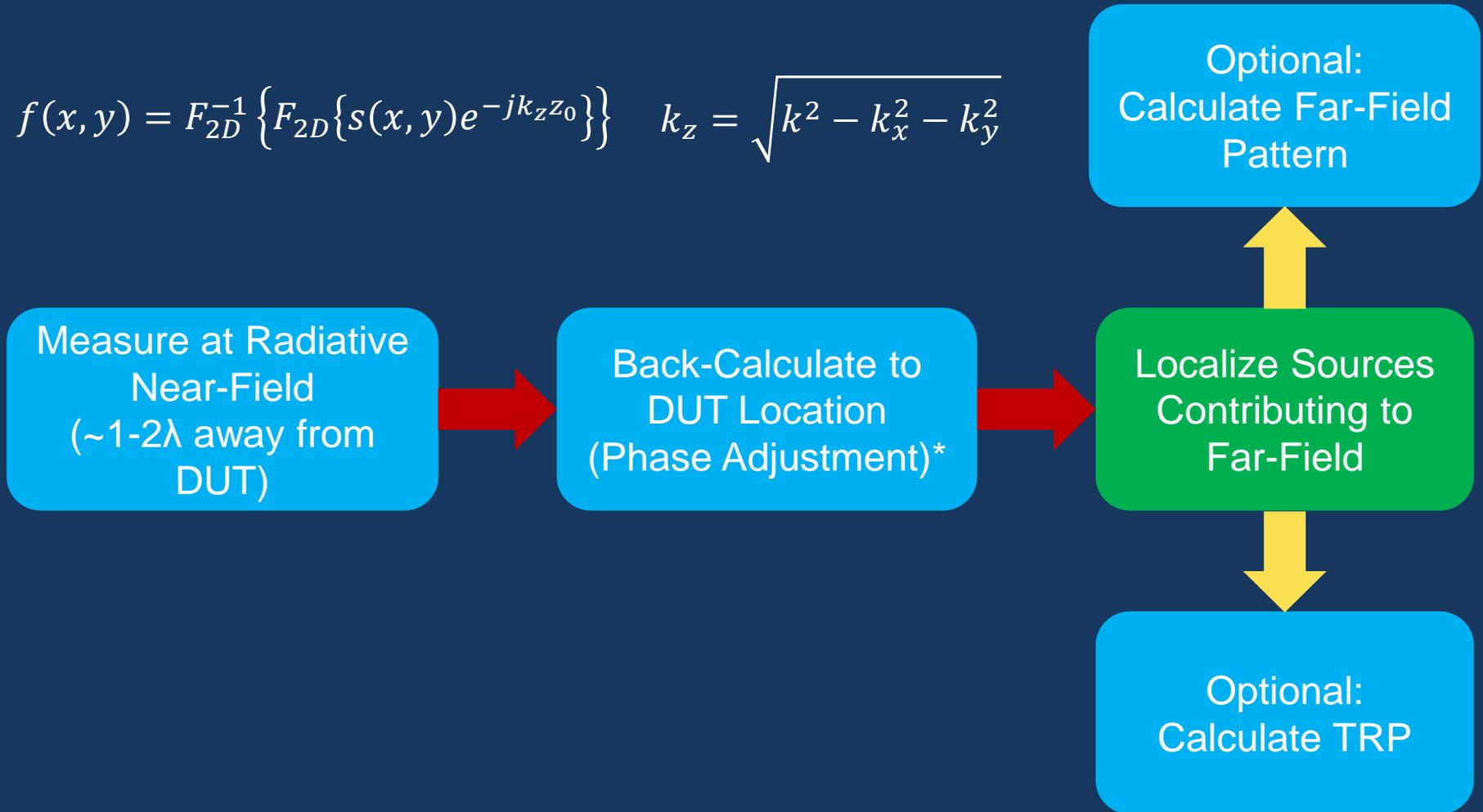
Max Ez



Max |E|

Emission Source Microscopy (ESM)

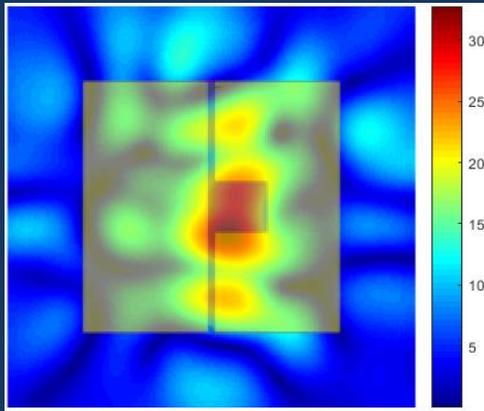
$$f(x, y) = F_{2D}^{-1} \left\{ F_{2D} \left\{ s(x, y) e^{-jk_z z_0} \right\} \right\} \quad k_z = \sqrt{k^2 - k_x^2 - k_y^2}$$



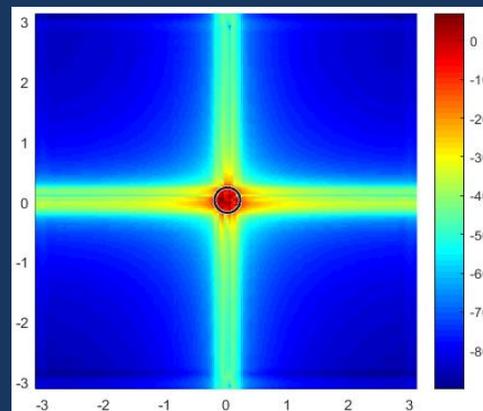
* Using Range Migration Algorithm (RMA) or Synthetic Aperture Radar (SAR)

k-Space and Propagating Wave

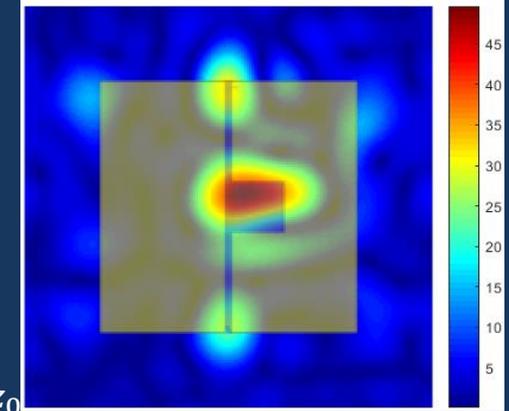
$$f(x, y) = F_{2D}^{-1} \left\{ F_{2D} \left\{ s(x, y) e^{-jk_z z_0} \right\} \right\} \quad k_z = \sqrt{k^2 - k_x^2 - k_y^2}$$



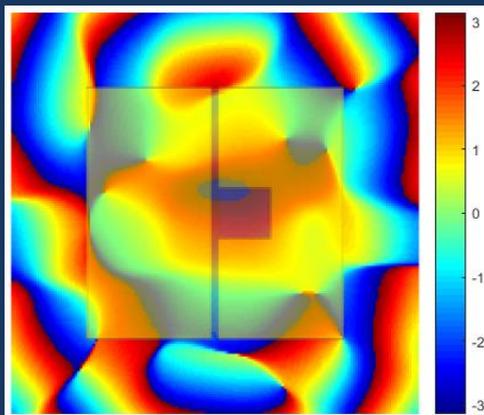
Scanned |Ex|



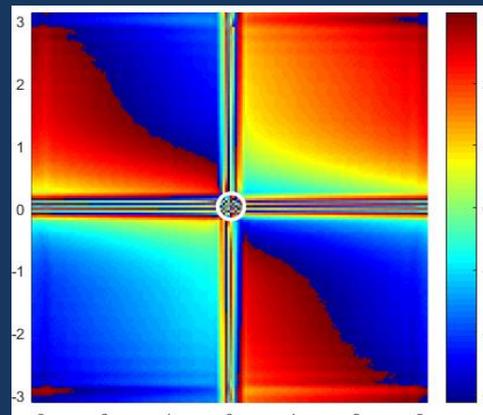
k-Space



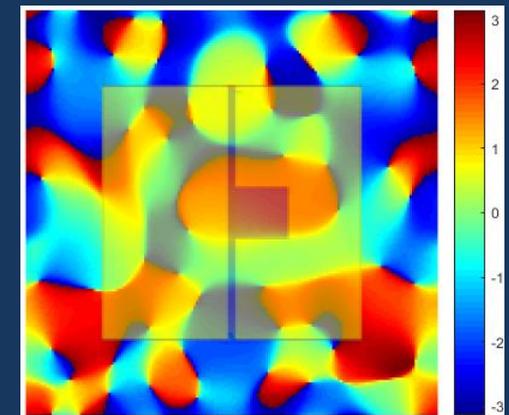
Focused |Ex|



Scanned ≠ Ex



≠ k-Space



Focused ≠ Ex



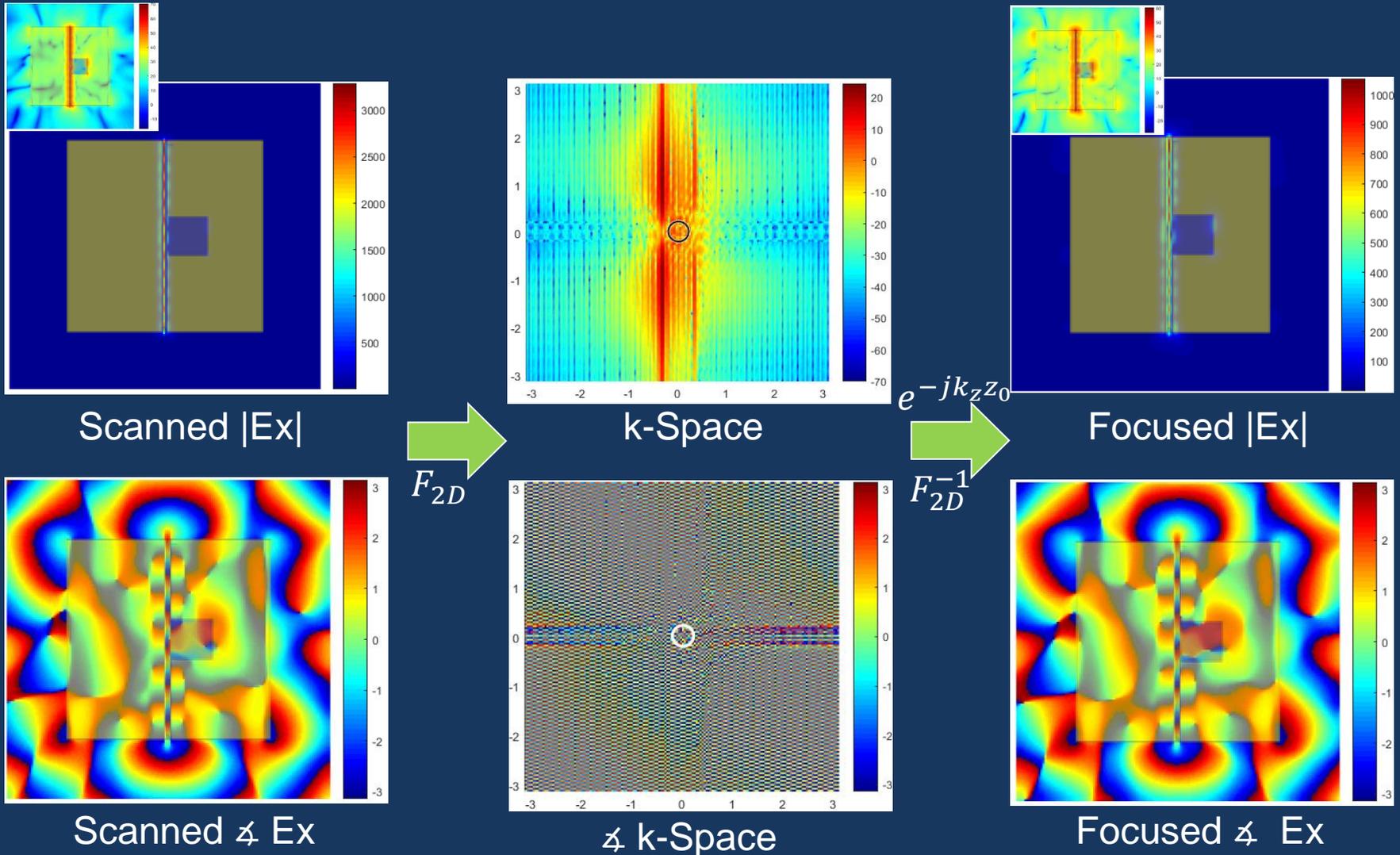
F_{2D}



$e^{-jk_z z_0}$

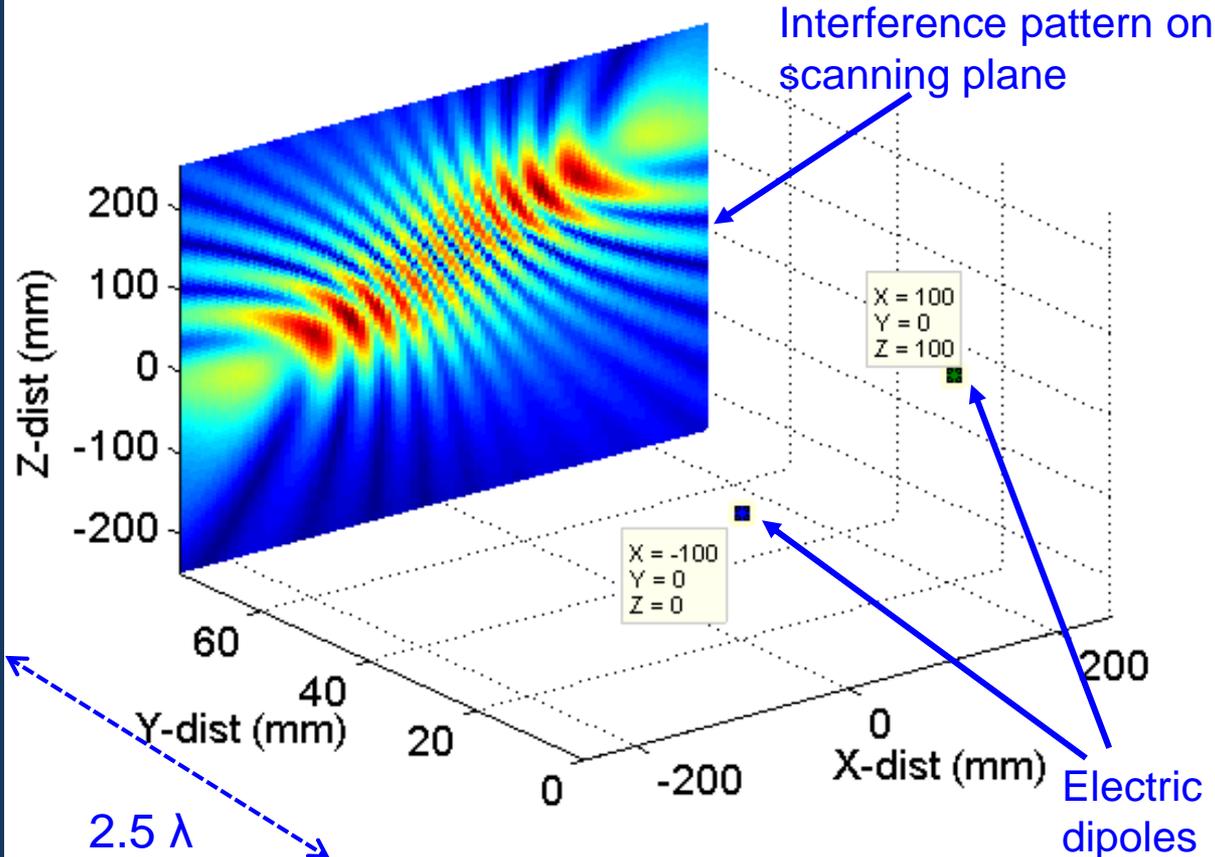
F_{2D}^{-1}

k-Space and Evanescent Wave



Ideal Dipole

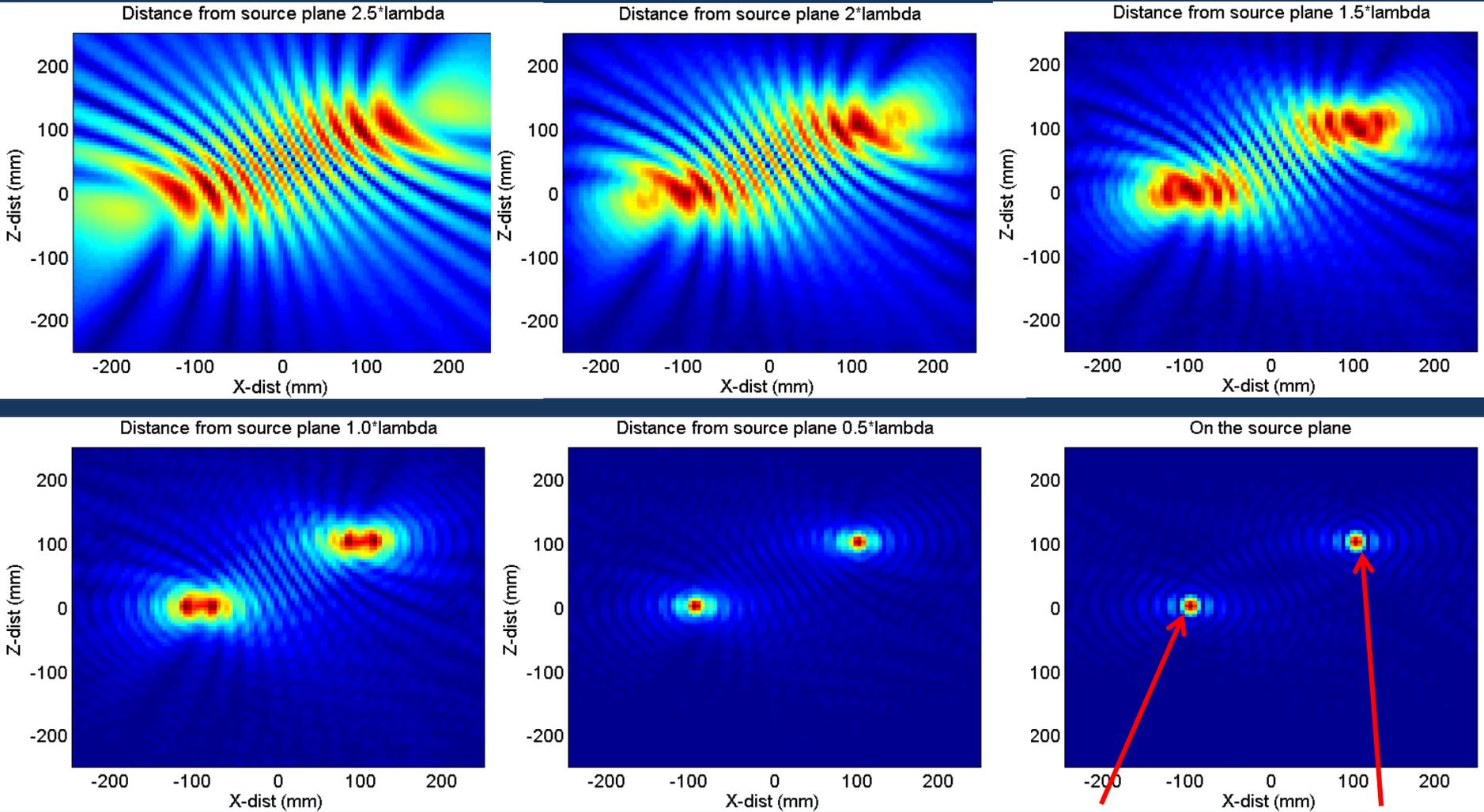
Dipole locations and measurement plane



Two dipoles are placed
Dipole 1 at (-100,0,0) mm,
Dipole 2 at (100,0,100) mm

E fields components
Frequency = 10 GHz
Grid spacing = 0.5 mm
Distance = 2.5λ
Resolution ~ 15 mm

Focusing Lens at Different Distances

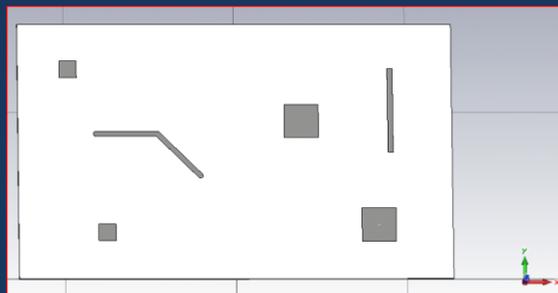
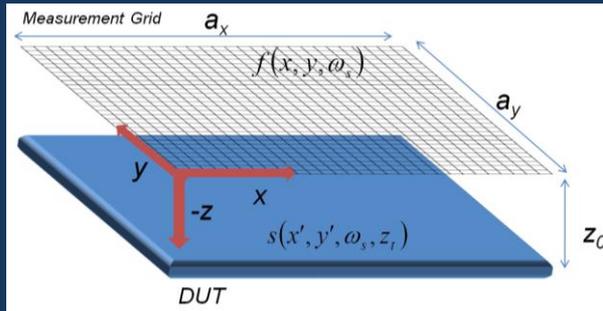


Correct location of dipoles is determined

Dipole 1 at
(-100,0,0) mm

Dipole 2 at
(100,0,100) mm₁₈

Applications of ESM

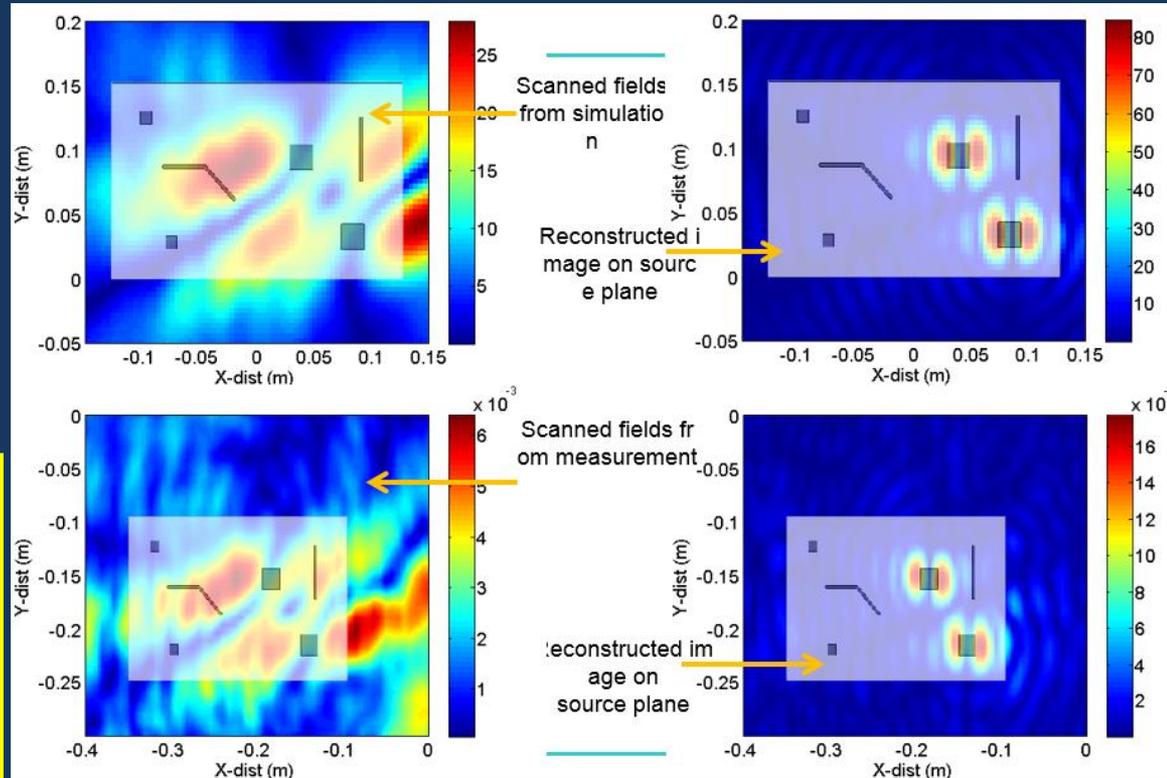


ESM Application of Synthetic Aperture Antenna (SAR) to EMC

- Identification of emission source
- FF estimation
- Total radiated power calculation

5 cm Away from DUT

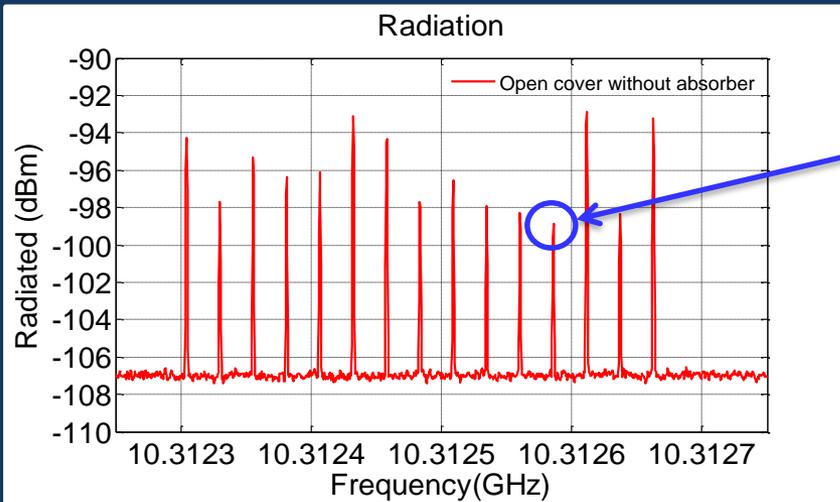
Focused Image



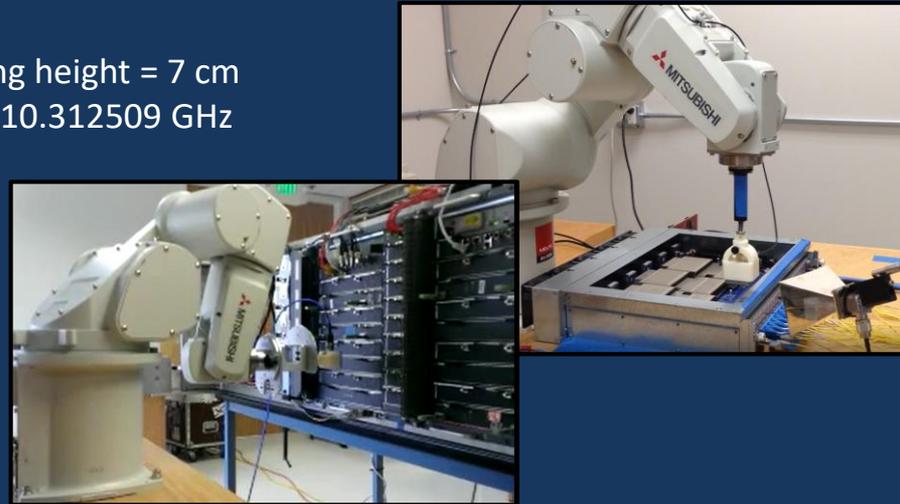
Measurement Setup:

- The measurement is performed at 8.2 GHz and at 5 cm away from DUT.
- Using VNA and open-ended waveguide used.

Applications of ESM



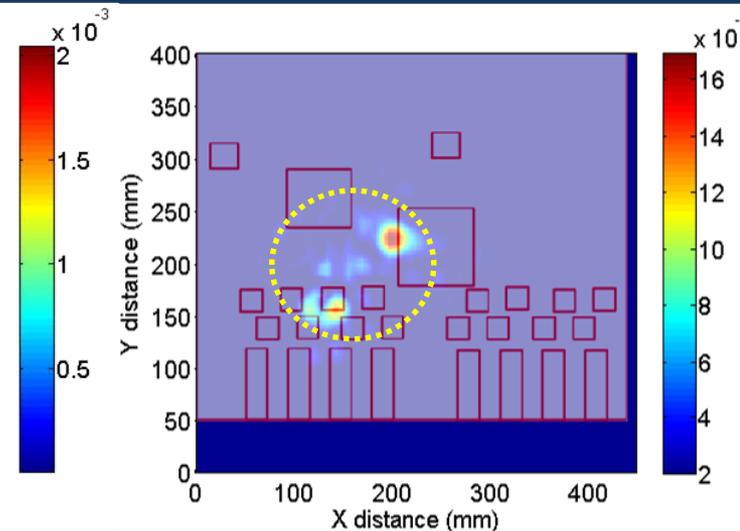
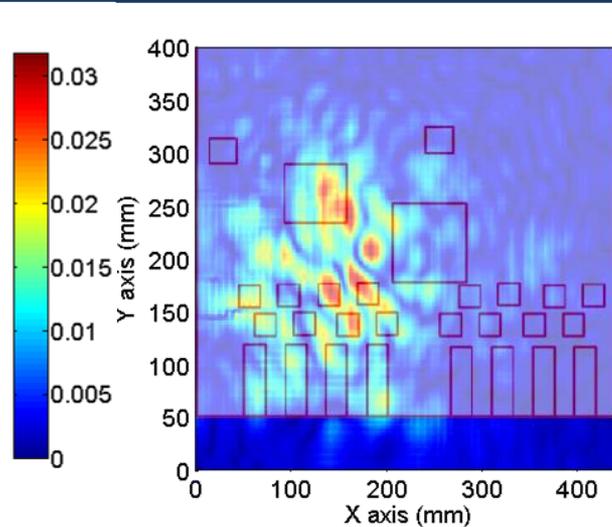
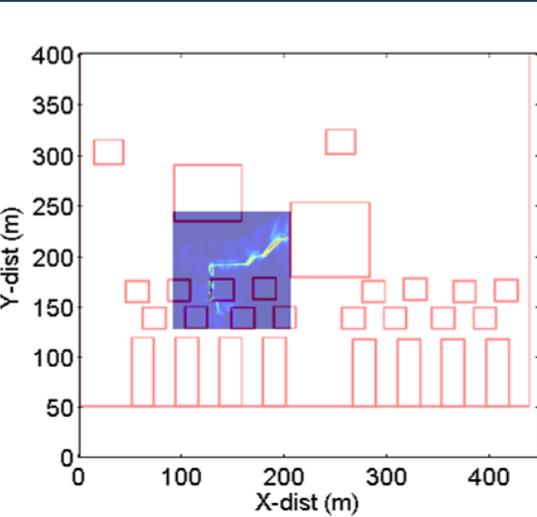
Scanning height = 7 cm
Freq = 10.312509 GHz



Near-Field Hx @ 2 mm

Scanned Ex @ 7 cm

Focused Ex @ 0 cm



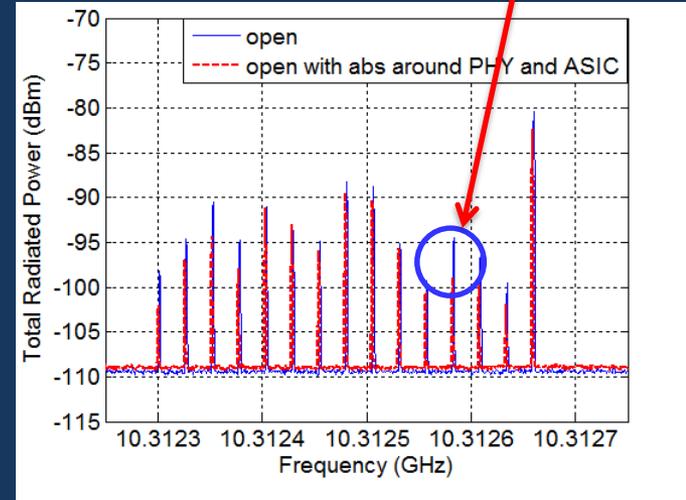
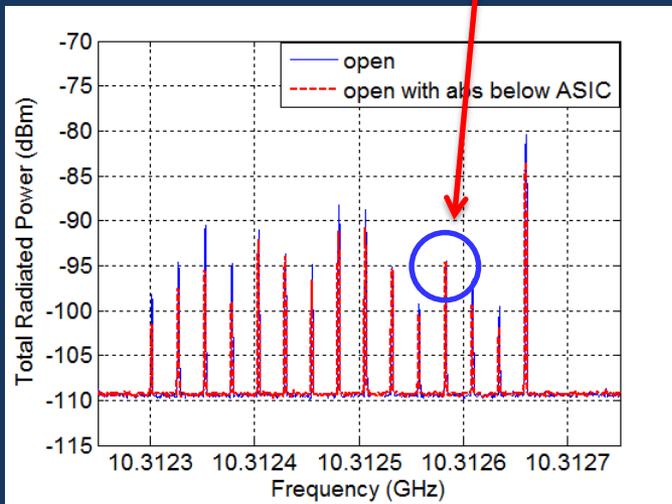
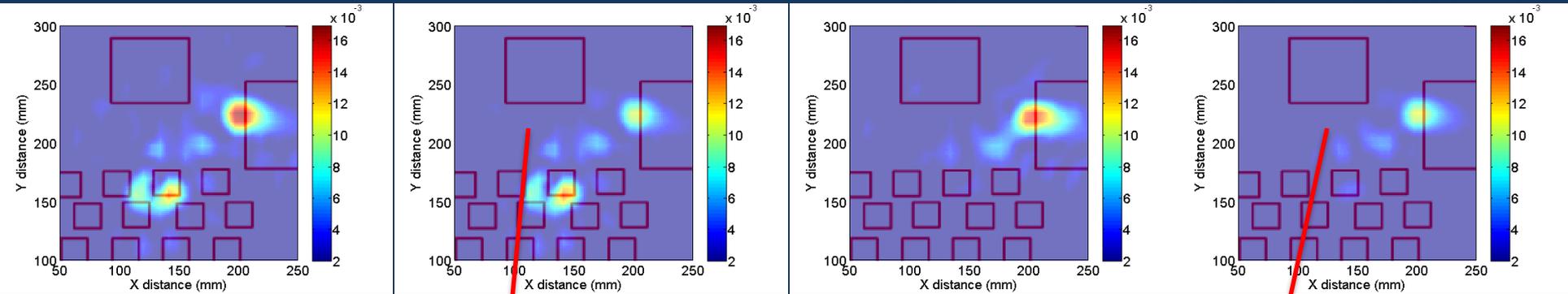
Applications of ESM

Without absorbing material

With absorbing material below ASIC

With absorbing material around PHY

With absorbing material around PHY and below ASIC



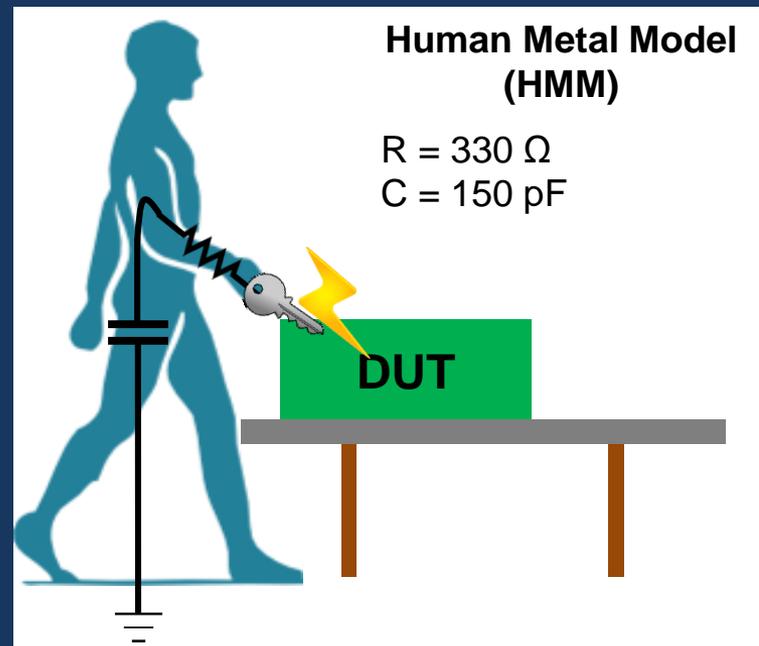
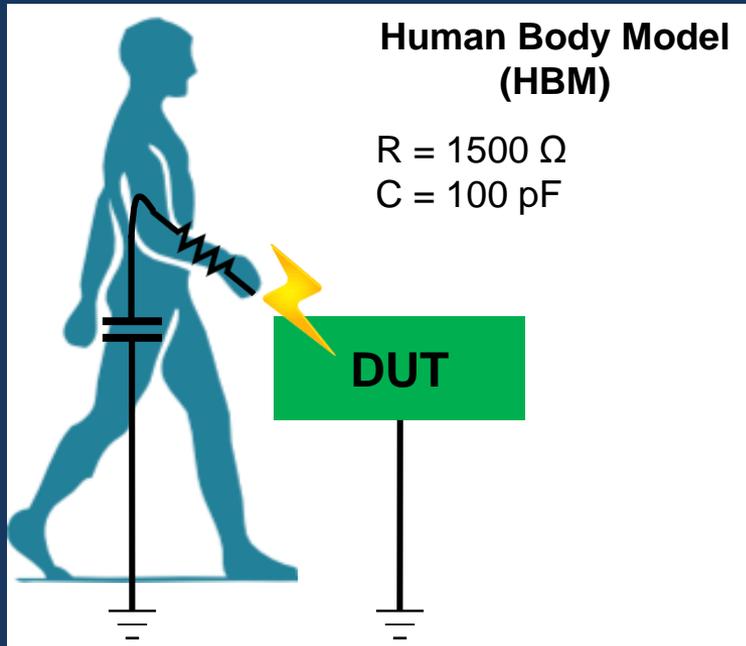
	TRP from R-Chamber	Calculated From ESM
Reduction in TRP	0-1 dB	0-1 dB

	TRP from R-Chamber	Calculated From ESM
Reduction in TRP	4-5 dB	4-5 dB

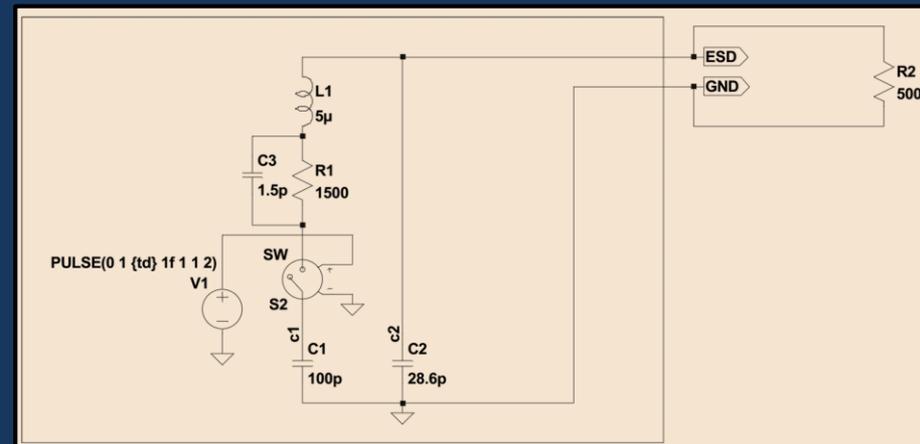
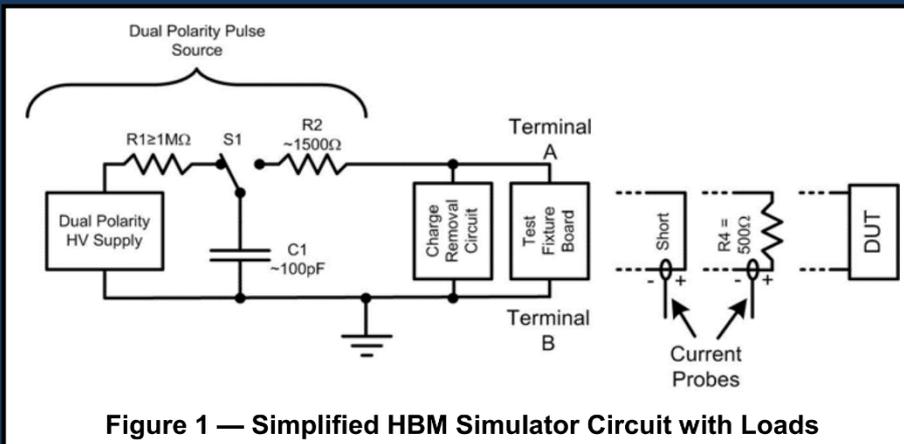
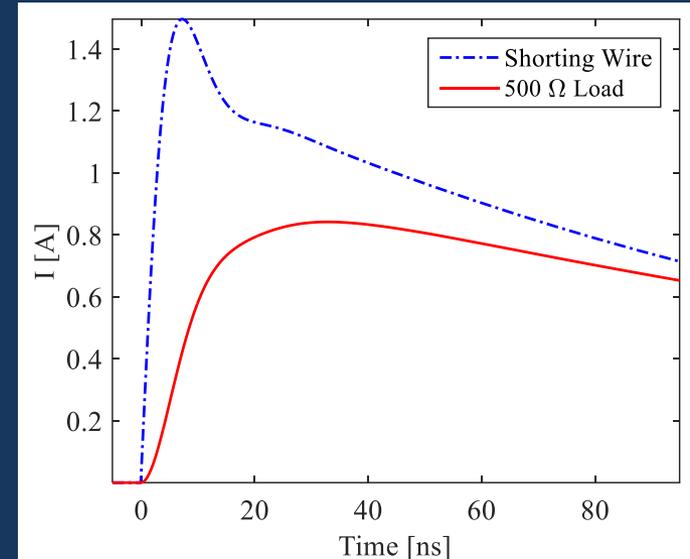
- EMI scanning is a powerful tool for identifying near-field sources.
- Measuring the phase distribution, in addition to magnitude, helps with identifying sources that contribute to far-field using ESM.
- Near-field to far-field transformation and total radiated power estimation are useful applications of phase measurement.

ESD Susceptibility Scanning

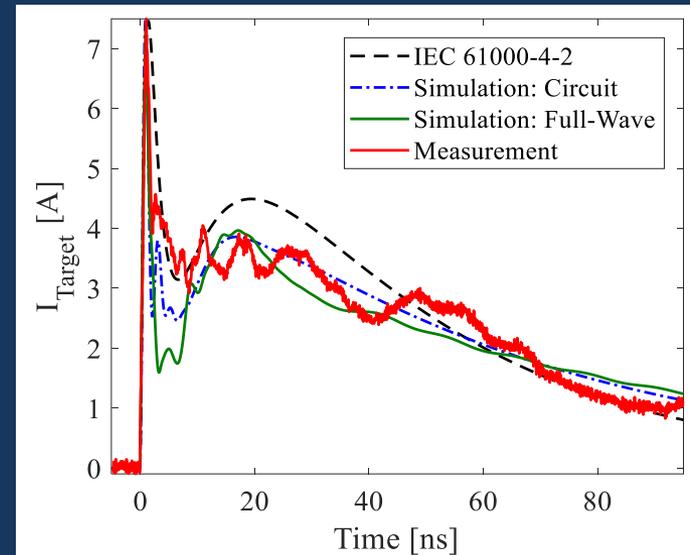
Electrostatic Discharge (ESD)



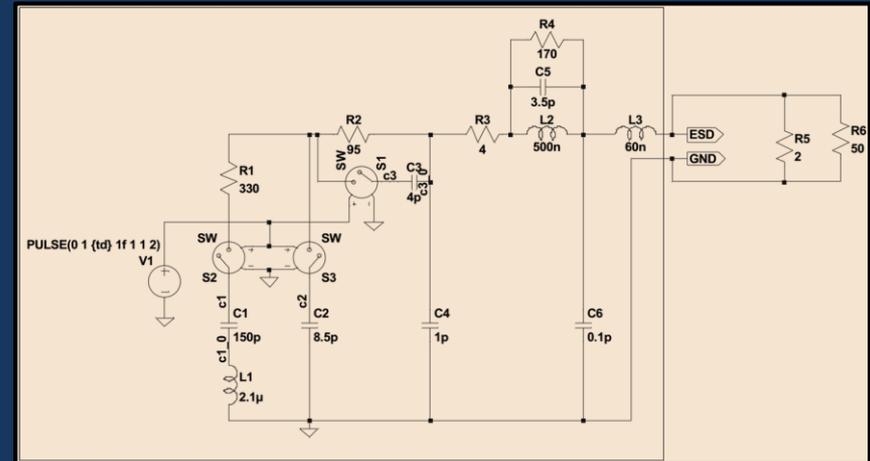
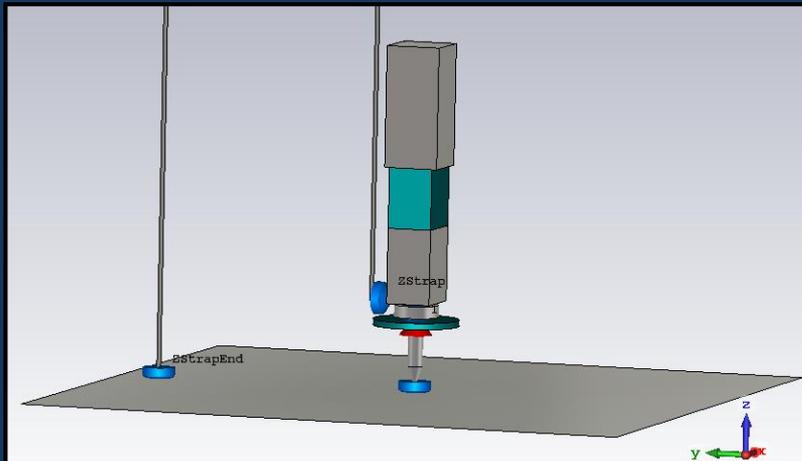
HBM Waveform



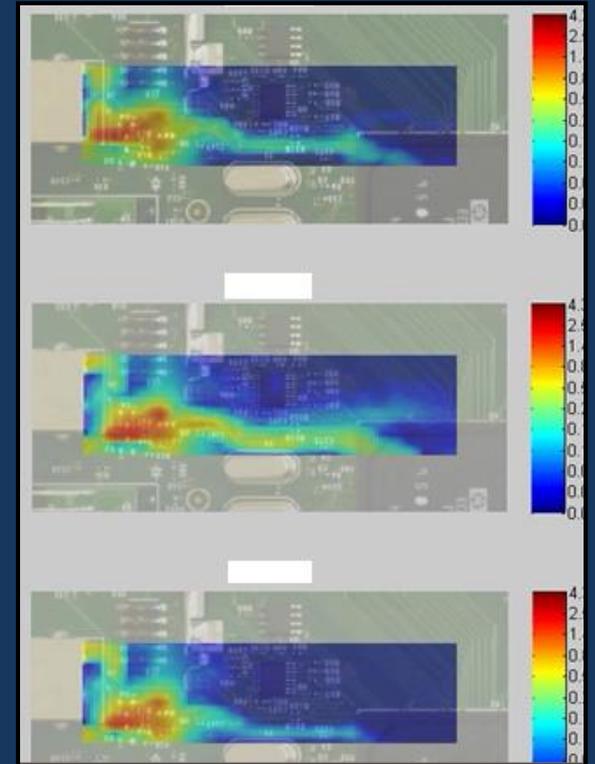
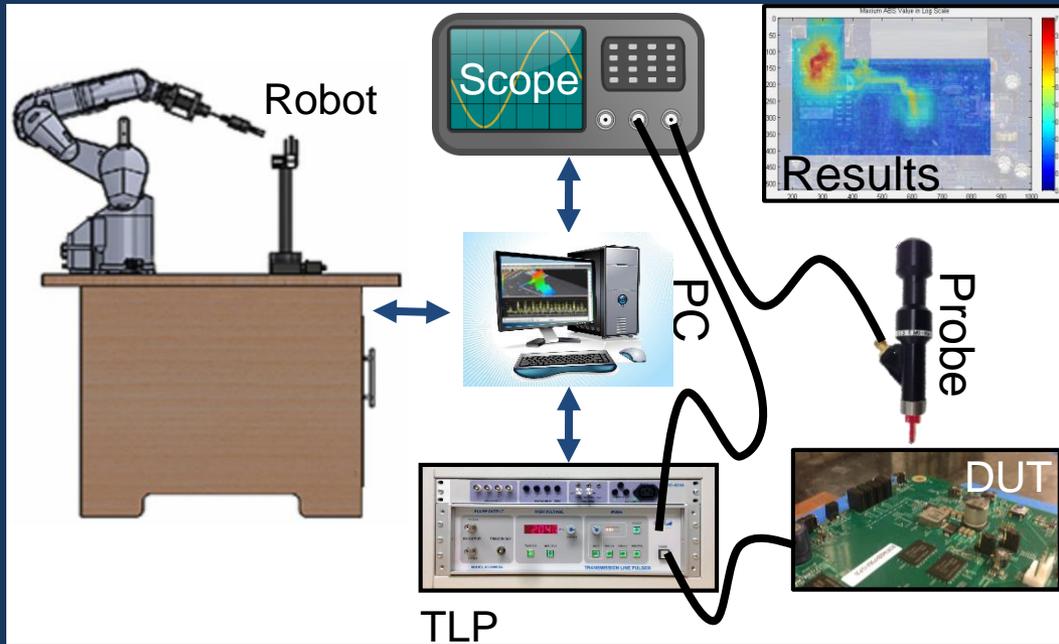
HMM Waveform



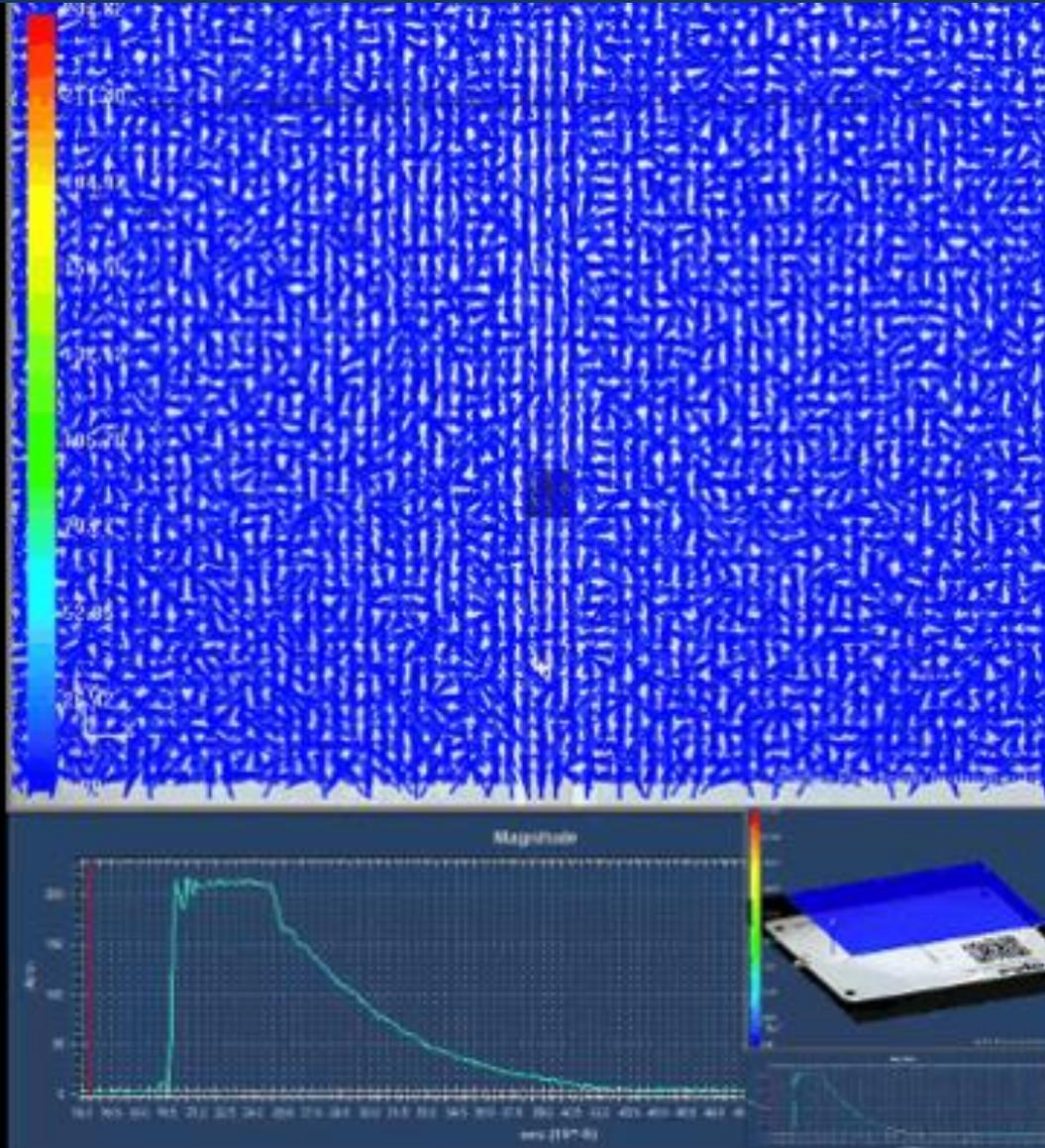
$$I(t) = \frac{I_1}{k_1} \cdot \frac{\left(\frac{t}{\tau_1}\right)^n}{1 + \left(\frac{t}{\tau_1}\right)^n} \cdot e^{\left(\frac{-t}{\tau_2}\right)} + \frac{I_2}{k_2} \cdot \frac{\left(\frac{t}{\tau_3}\right)^n}{1 + \left(\frac{t}{\tau_3}\right)^n} \cdot e^{\left(\frac{-t}{\tau_4}\right)}$$



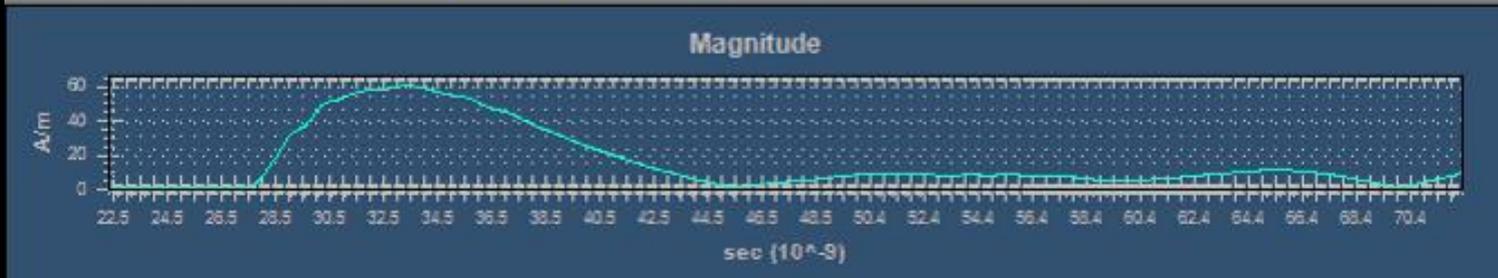
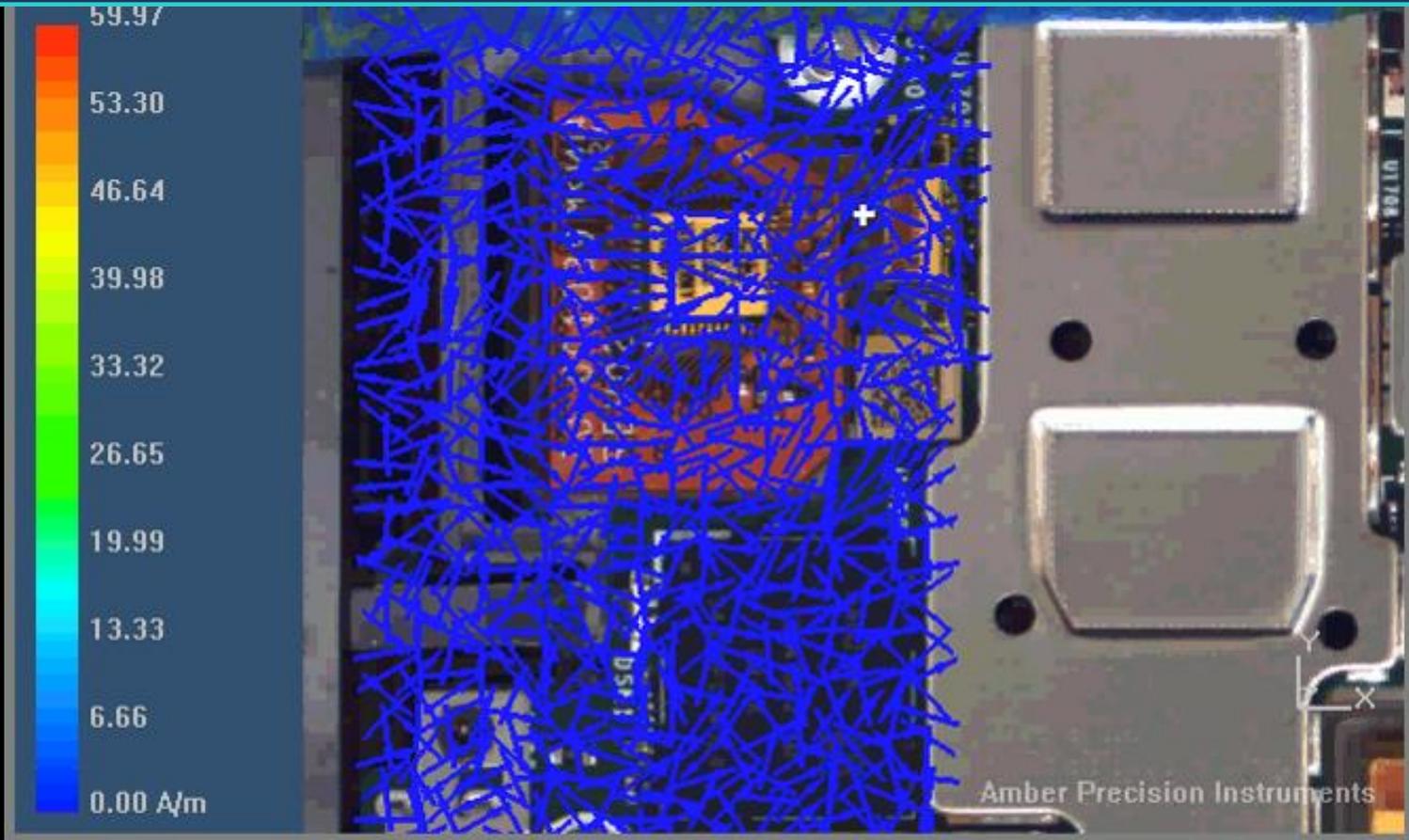
ESD Current Spreading Scanning



Current Spreading on Microstrip



Current Spreading on Flex PCB



From ESDA:

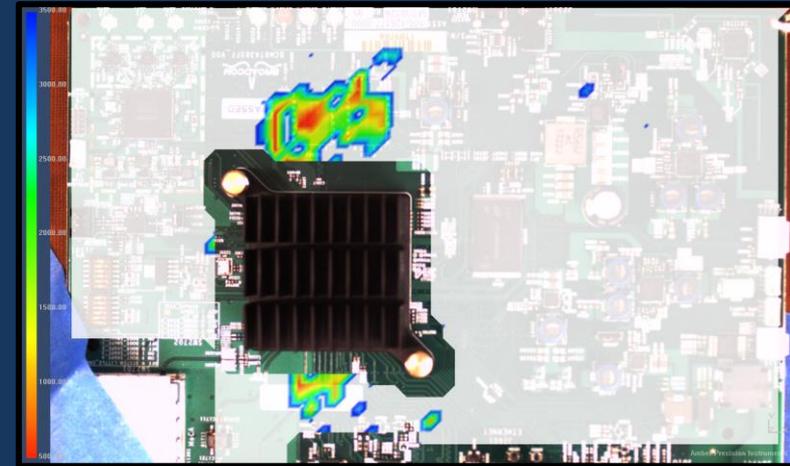
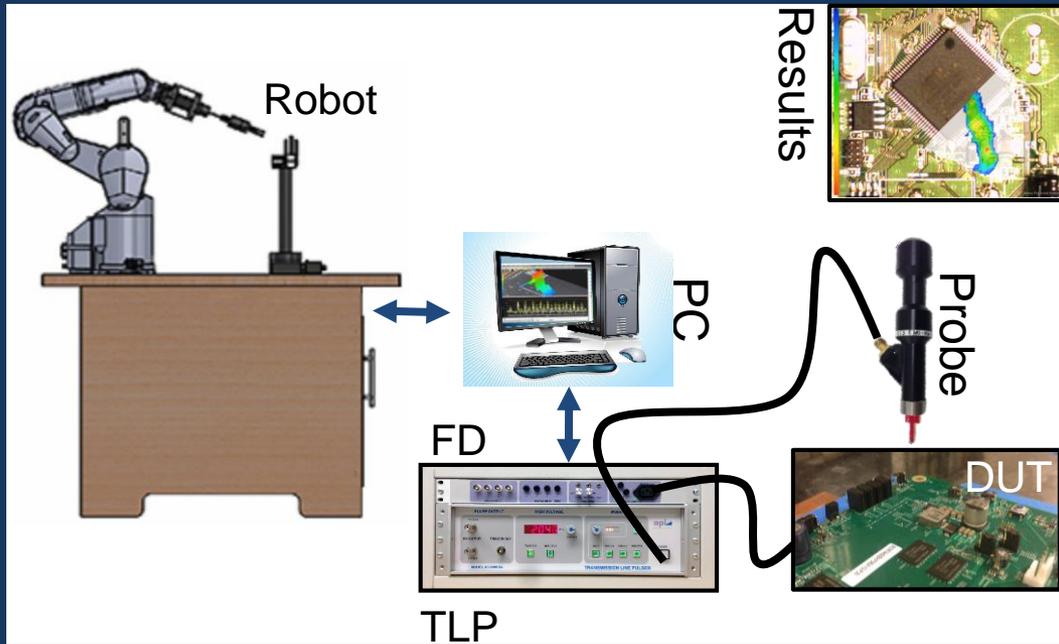
***For Electrostatic Discharge Sensitivity Testing –
Near-Field Immunity Scanning –
Component/Module/PCB Level***

***An American National Standard
Approved September 14, 2015***

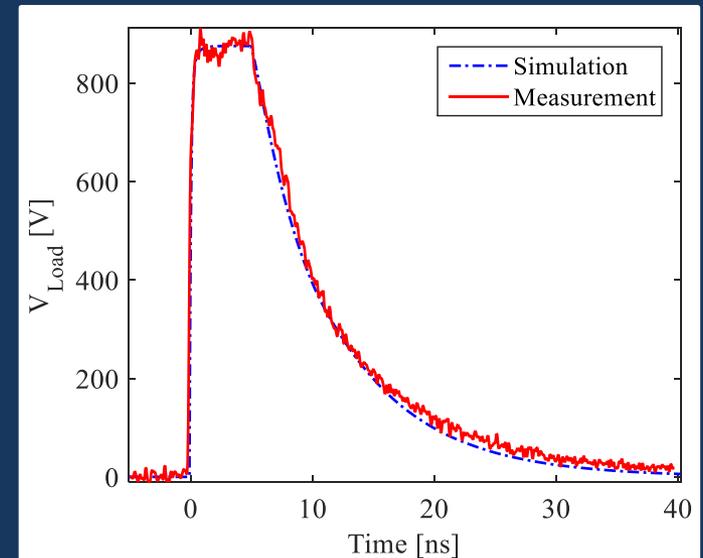
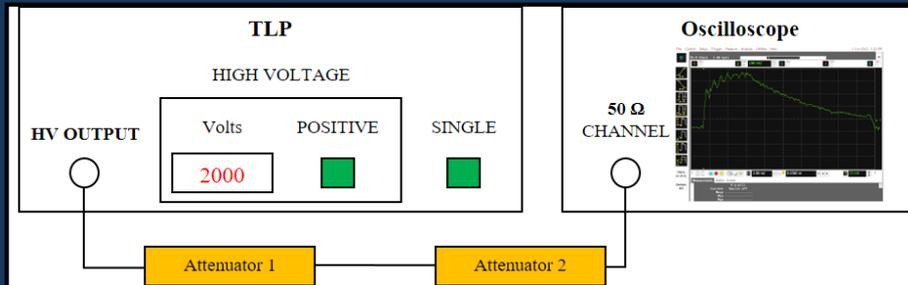


ESD scanning technology is widely accepted as a powerful tool for root cause analysis and screening high immunity components, modules and systems

ESD Immunity Scanning



TLP Waveform

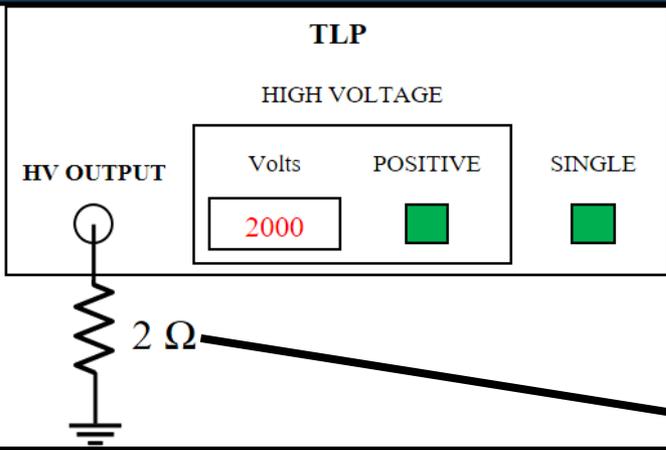


$$V_{TLP} = 2 \text{ kV}$$

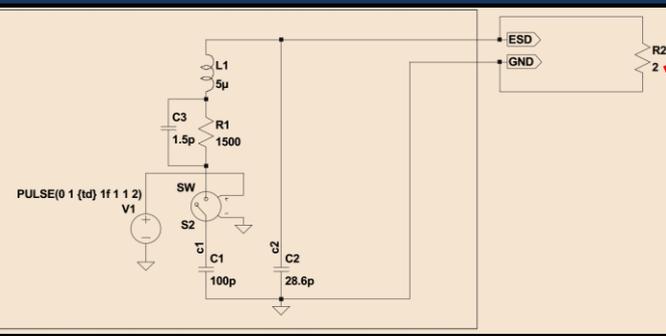
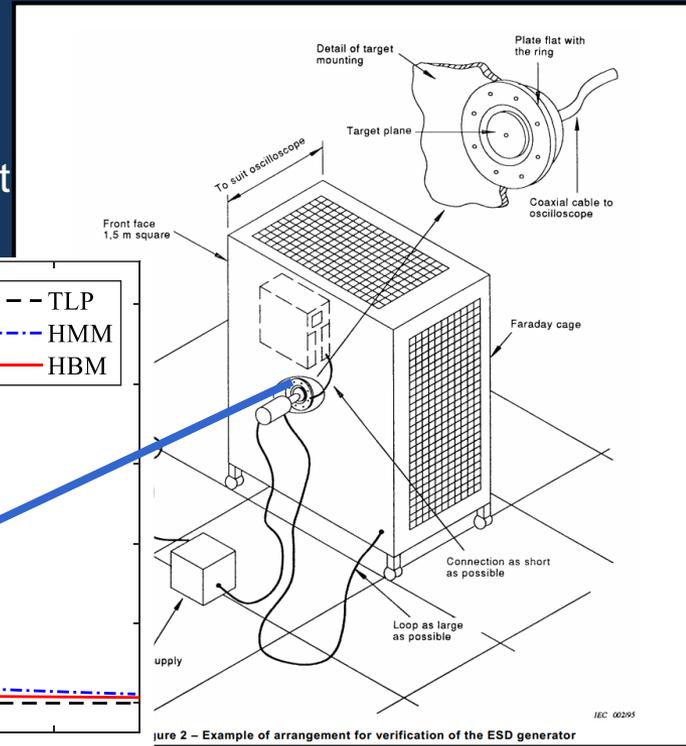
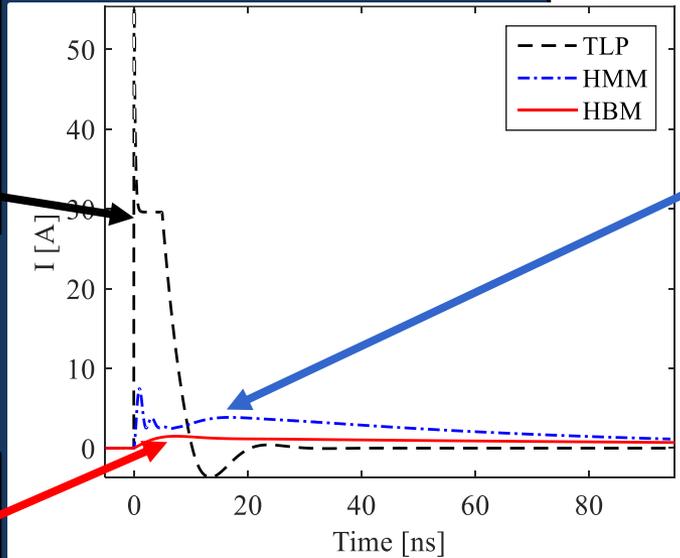
$$T_r = 500 \text{ ps}$$

$$T_f = 33 \text{ ns}$$

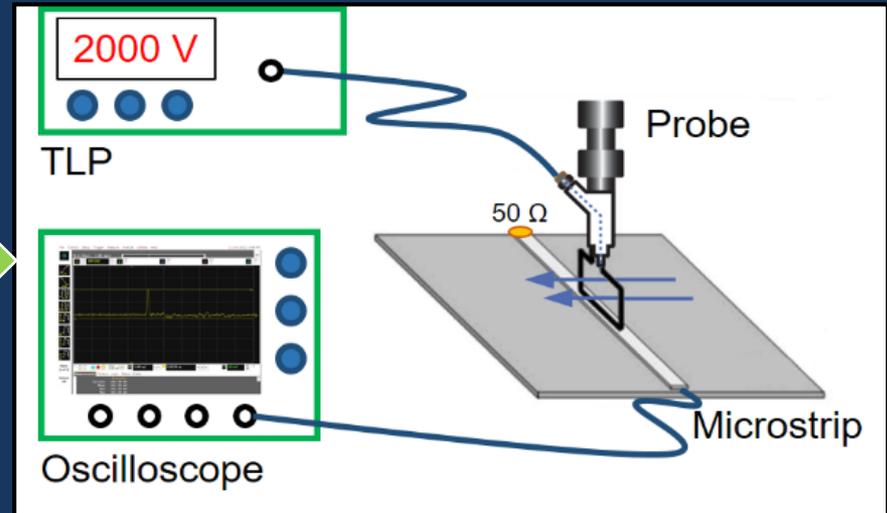
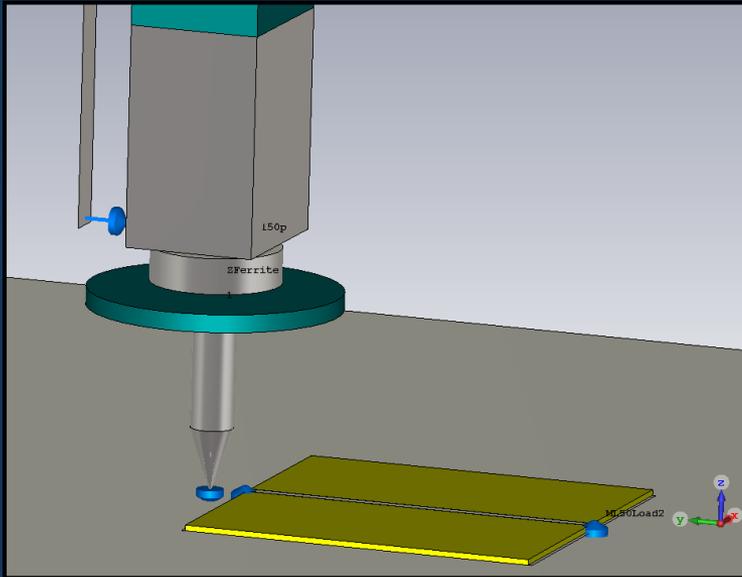
Current Waveforms: HBM vs HMM vs TLP



Simulated discharge current waveform on 2 Ω load



HMM vs ANSI/ESD SP14.5-2015 Simple Structure



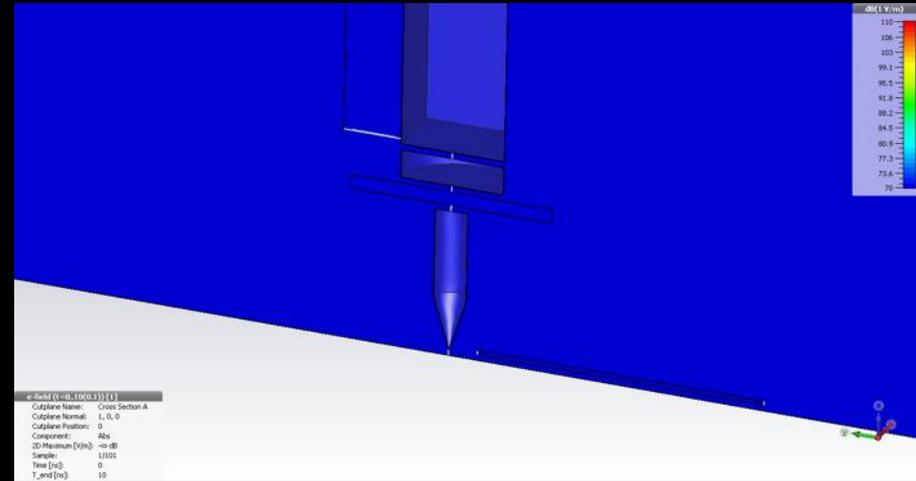
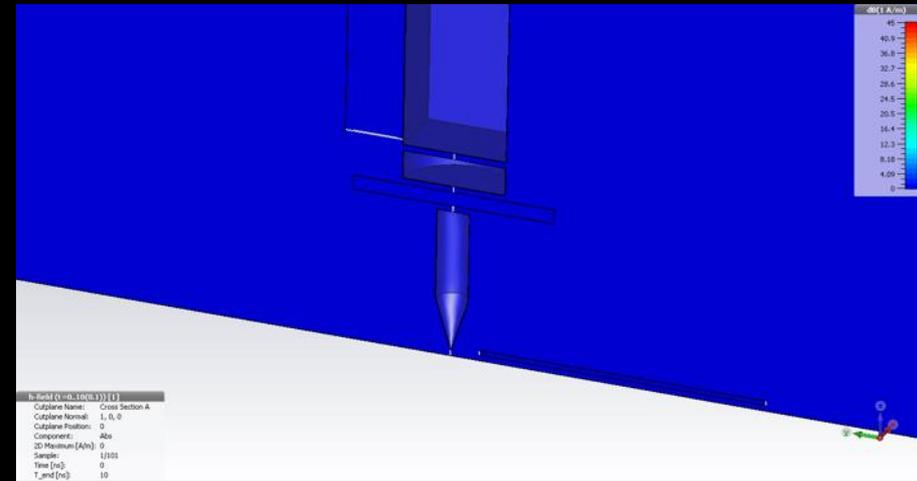
50 ohms microstrip (3 mm wide trace)
Board dimension: 100 x 100 mm²
Board elevation from HCP: 1 mm
ESD generator distance to board: 10 mm
ESD generator setting: 2 kV CD

50 ohms microstrip (3 mm wide trace)
Board dimension: 100 x 100 mm²
Probe: 2 mm or 5 mm loop H-field
Mechanical probe height from trace: 0 mm
TLP setting: 2 kV

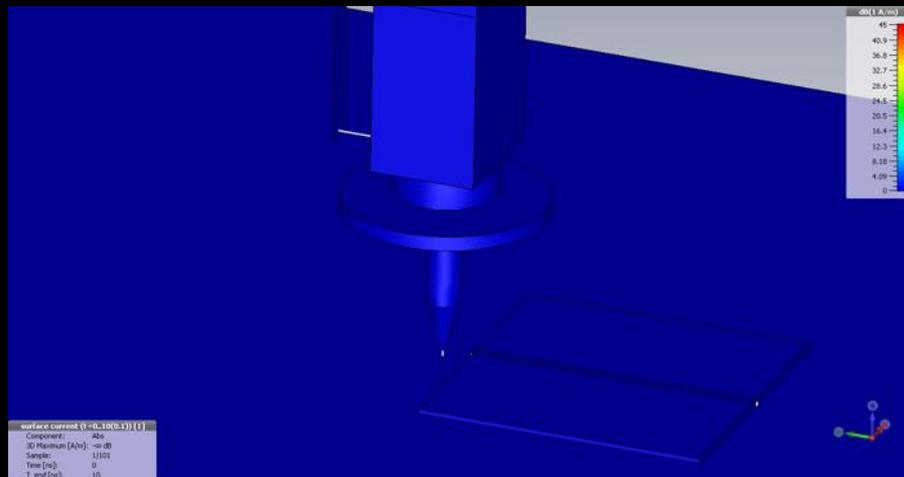
Field Coupling to Microstrip

H-Field

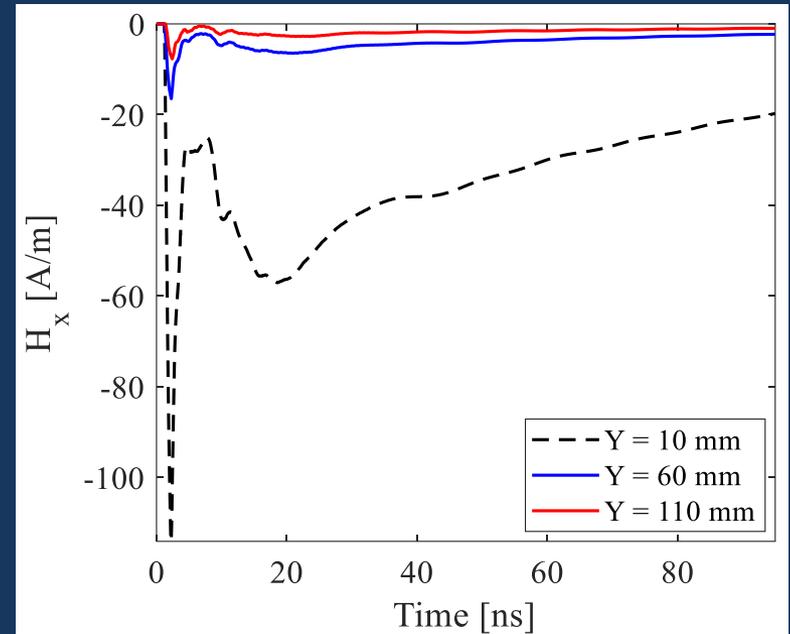
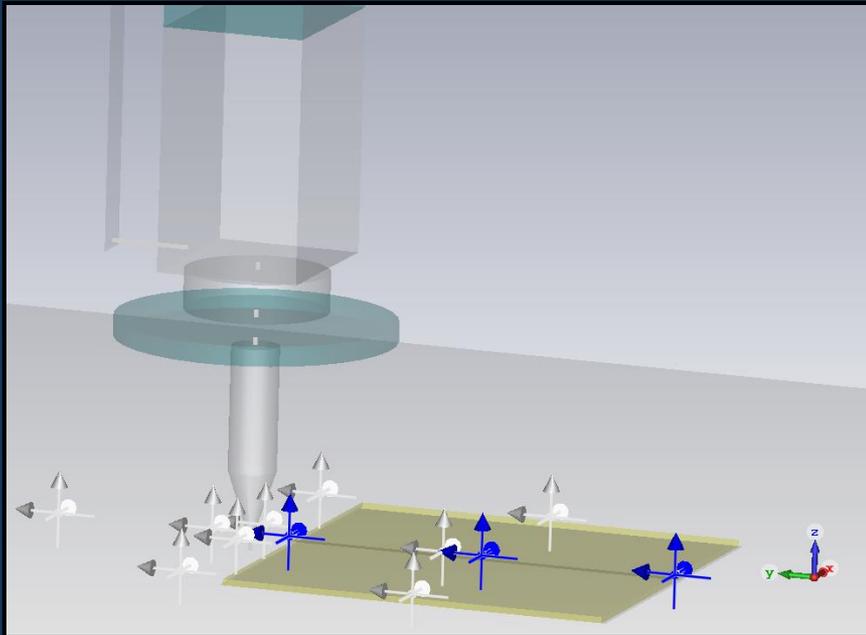
E-Field



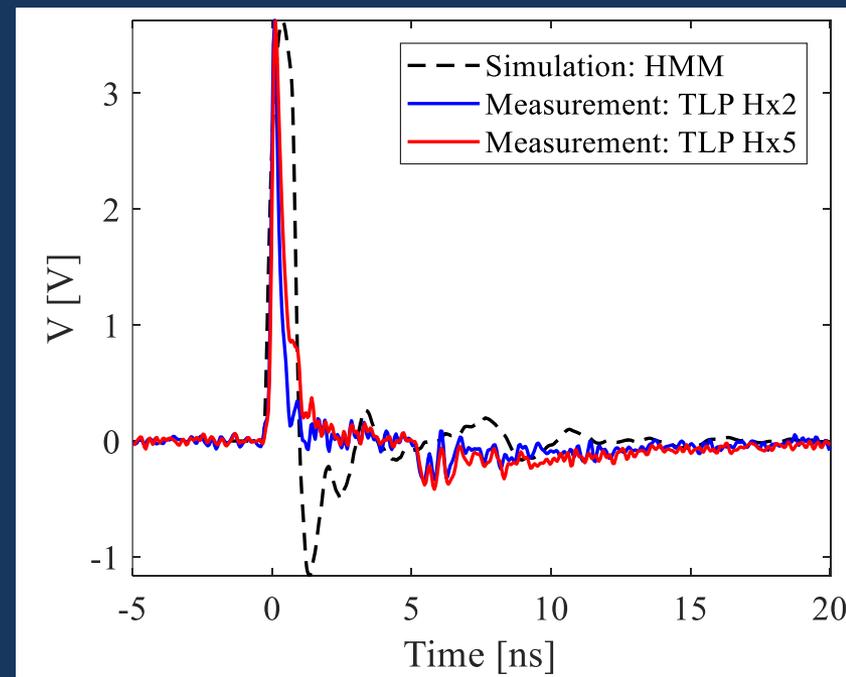
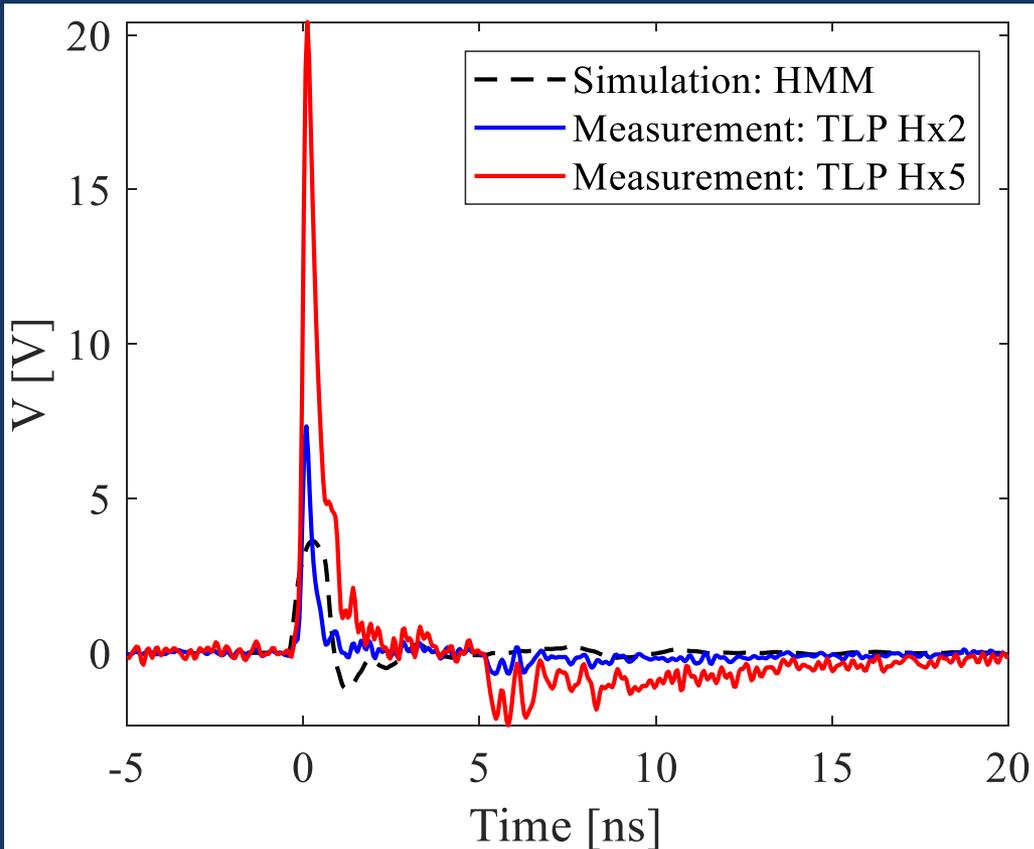
Surface Current Density



Field Attenuation from ESD



HMM vs Near-Field Injection



$$V_{eq} = \frac{1.98 \times V_{ESD}}{A_{ef}} \left(\frac{r}{2.4} \right)^\alpha \cdot \left(\frac{60}{R} \right)^\beta$$

Effect of IC Fab on ESD

White Paper 3 Part II specifically covers in detail **an overview of system ESD stress application methods, system diagnostic techniques to detect hard or soft failures, and the application of tools for susceptibility scanning.** For example, as illustrated in Figure 2, these types of advanced tools can be used to differentiate the characteristics of products and enable proper system protection methodology*.

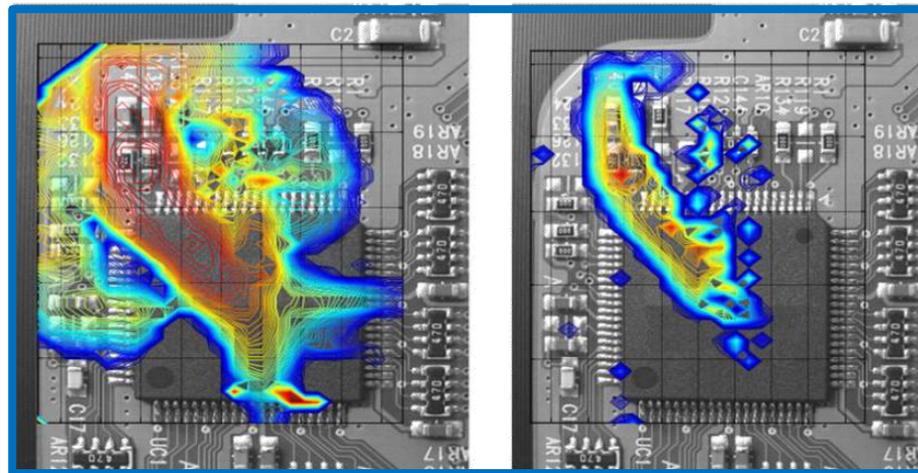


Figure 2: Susceptibility scanning using pulse techniques on Product A (left) and Product B (right)
(Courtesy of Amber Precision Instruments)

* Quote from the ESDA White paper 3, Part II, page 18.

** Product A and Product B are functionally identical ICs from different vendors.

- Conducted susceptibility to an ESD even can be analyzed by measuring and visualizing scanned surface current density on the DUT.
- Susceptibility to near-field effects of an ESD event can be emulated with near-field injection.
- Near-field injection per ANSI/ESD SP14.5-2015 reproduces same failures as IEC 61000-4-2.

Thank You!

Questions?

- Application of Emission Source Microscopy Technique to EMI Source Localization above 5 GHz [[Link](#)]
- Emission Source Microscopy Technique for EMI Source Localization [[Link](#)]
- EMI Mitigation with Lossy Material at 10 GHz [[Link](#)]
- Compressed Sensing for SAR-Based Wideband Three-Dimensional Microwave Imaging System Using Non-Uniform Fast Fourier Transform [[Link](#)]
- Introduction to Fourier Optics [[Link](#)]
- Synthetic Aperture Radar Signal Processing with MATLAB Algorithms [[Link](#)]
- Wikipedia: Synthetic Aperture Radar [[Link](#)]